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Carbon-based materials for stable, cheaper and large-scale processable perovskite solar cells

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Almost ten years after their first use in the photovoltaic (PV) field, perovskite solar cells (PSCs) are now hybrid devices that, in addition to having reached silicon performance, can accelerate the energy transition and boost the use of abundant elements for their manufacturing process. However, noble metals (in particular gold) represent the most typically used sources for back electrode fabrication, and this issue has been intensively considered by the research community in the last five years. This review shows how the most promising solution, considering also the need to develop a large-scale production process, is based on the use of carbon-based materials for the preparation of back electrodes. Graphite, carbon black, graphene and carbon nanotubes (CNTs) have been proposed, functionalized and characterized, leading to laboratory-scale solar cells and modules capable of providing excellent efficiencies and ensuring stability greater than those of gold-based devices. Strengthened by these results and its hydrophobizing properties, carbon has also started to be used as an electron transporting material (ETM), with excellent results on both rigid and flexible substrates. This review discusses the major advances and the updated state-of-the-art in the carbon-based PSC scenario, keeping a solid trajectory where the accessibility, low cost, high electrical conductivity, chemical stability and controllable porosity of carbon are highlighted and exploited in the design of upscalable hybrid solar cells.

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Broader context

Today, more than 75% of the world energy demand is met by traditional, non-sustainable energy resources, mainly based on coal, natural gas and oil. Photovoltaics represents a concrete action to mitigate fossil fuel consumption, and among all the developed solar cells, perovskite-based ones have shown the highest increase in terms of efficiency (currently above 25%). Halide perovskites, as a family of new-generation semiconductor materials, are also exploitable for light-emitting devices, photodetectors and memristors, but their use in photovoltaics gives rise to outstanding performances. Here, photogenerated charges pass through electron/hole transporting materials and are transferred to the external circuit by front and back electrodes. While the front electrode is a common conductive glass, many issues are now under study concerning the back electrode, traditionally made of gold. Indeed, replacing this expensive metal with a much cheaper alternative is vital for realizing affordable solar technologies. Carbon, in its multiple forms, represents the winning solution and the scientific community has recently shown its large scale processability, its power as a stability booster and some interesting effects at the perovskite/electrode interface. This review shows how carbon is becoming the winning ingredient for the scaling up and worldwide diffusion of perovskite solar cells.

1 Introduction

Among all PV fields, PSCs have shown the highest increase in terms of power conversion efficiency (PCE), passing from 3.8%¹ to 25.2%² in just a few years.^{3–7} Perovskites are materials with the generic formula ABX_3 , where A is an organic larger cation, situated in the eight corners of the unit cell, with cubooctahedral coordination, B is a metal cation located at the body center, and X represents an anion that binds them both.^{8,9}

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This kind of material has attracted much attention, due to its superb characteristics, such as strong and broad optical absorption from the visible to the near-infrared (NIR) range,¹⁰ long carrier lifetime, long diffusion length (from 100 nm to 1 μ m), a direct optical band-gap of 1.5 eV and low exciton binding energy.^{11–13} In addition, these semiconductors offer good versatility and processability from solution.^{14,15} In PSCs, perovskites are used as light absorber and charge transporting materials.^{16–18} One of the most commonly used perovskites is the hybrid organic-inorganic compound, $CH_3NH_3PbI_3$.^{19–21}

One of the main drawbacks toward the commercialization of PSCs is the use of noble metals, such as gold and silver, as back electrodes, thus limiting their large-scale application. Gold and

silver are expensive rare metals and their deposition requires a highly energy-consuming vacuum evaporation method.²² In addition, silver and gold electrodes may deteriorate cell performance,²³ due to migration of halogen atoms from the perovskite phase, with formation of silver and gold halides.^{24–26}

The most common carbon-based materials used in the PSC field are graphite/amorphous carbon, graphene, and CNTs. They represent a suitable solution to substitute noble metals, due to their low cost, high conductivity, eventual low-temperature processing (100 °C)^{1,27,28} and work function close to that of gold (5.0 and 5.1 eV, respectively).^{29,30} Another advantage of carbon-based components reflects on perovskite degradation in the presence of water, that leads to the formation of the hydrated phases $\text{CH}_3\text{NH}_3\text{PbI}_3 \cdot \text{H}_2\text{O}$ and $(\text{CH}_3\text{NH}_3)_4\text{PbI}_6 \cdot 2\text{H}_2\text{O}$,³¹ while the formation of the monohydrate phase is reversible, the dihydrate phase degrades irreversibly to yellow PbI_2 and $\text{CH}_3\text{NH}_3\text{I}$.³² Conversely, carbon-based materials can improve PSC stability due to their highly hydrophobic nature that leads to the prevention of moisture penetration in the perovskite layer, even without carrying out the sealing process.²⁴

Nonetheless, carbon-based materials also present many drawbacks, associated especially with their processability on a large scale. For example, graphene, the 2D layer of graphite, is a very versatile material with metal-like properties; however, it is difficult to be obtained by mechanical or chemical exfoliation on a large scale. The dispersion of graphene layers from graphite requires a large amount of organic solvents, such as dimethylformamide; on the other hand, the epitaxial growth on SiC by vacuum graphitization has the disadvantages of high temperature (1300 °C) and high costs of the monocrystalline SiC sheet.^{33,34}

Chemical vapour deposition (CVD) is more applicable on a large scale, but has hardly any control on film thickness and requires expensive substrates (Ni, Cu, Pd, Pt).³⁵ CNTs are composed of graphitic layers rolled up to form a cylinder. For this reason, in each tube, an elevated charge-transfer resistance is created.^{34,36} The problem is partially solved by the use of multi-walled CNTs (MWCNTs), which consist of multiple CNTs stacked together.

In some cases reported in this review, graphite and amorphous carbon require a high processing temperature. They form a rigid structure that impedes the penetration of the perovskite precursor solution. For this reason, the use of carbon black (CB) is necessary to break the oriented and impermeable graphite layer. In addition, in most cases, the small CB nanoparticles are obtained by the incomplete combustion of fossil fuels.

This review focuses on the current trends and major achievements obtained from hundreds of research teams working on carbon-based PSCs.³⁷ From our analysis of literature databases, it clearly emerges that graphite and CB represent the most credible realities if the target is – in a short time – a printable and industrially scalable solar energy conversion technology. We will show how the strategies for functionalizing and engineering the interfaces between carbon and perovskites or carbon and hole transporting materials (HTMs) strongly influence the cell PCE and stability. Finally, we will offer an overview of the state of the art of alternative carbon-based materials, such as CNTs and graphene, that show interesting aspects when low temperature processes or flexible device fabrications are envisaged. The achievement of stable, cheap and reproducible PSCs will be fundamental in view of their worldwide diffusion in the energy scenario, as well as integration with energy storage technologies.^{38–47}



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processes under ambient conditions. She was awarded with the best poster prize at the 19th International Symposium on Intercalation Compounds. She is the author of 2 publications in international peer-reviewed journals (*h*-index = 2).



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2 Graphite- and carbon black-based back electrodes

Generally speaking, a PSC is based on a perovskite layer^{48,49} sandwiched between an ETM and a HTM.^{50,51} The ETM usually consists of TiO_2 or another n-type semiconductor anode,^{52–54} while the back electrode is deposited on top of the HTM.^{55–57} For efficient charge extraction, the valence band (VB) and the conduction band of the perovskite should lie below the highest occupied molecular orbital (HOMO) of the HTM and under the lowest unoccupied molecular orbital (LUMO) of the ETM, respectively.^{58,59} After light absorption, in the perovskite layer an electron–hole pair is generated.^{60,61} Electrons are collected by the ETM and migrate towards the anode side, while holes are collected by the HTM and migrate towards the back electrode. The most common organic HTMs are expensive and require an inert atmosphere for the deposition process.^{62–64} They are also subjected to halide and metal ion migration,⁶⁵ resulting in the degradation of the cell.^{66–68} 2,2,7,7-tetrakis(*N,N*-di-*p*-methoxy-phenylamine)-9,9'-spirobifluorene (spiro-OMeTAD) is commonly used as a HTM in gold-based PSCs.⁶⁹ It needs to be doped with lithium bis(trifluoromethanesulfonyl)imide (LiTFSI), a hygroscopic and deliquescent salt that allows the penetration of water molecules, leading to the decomposition of the perovskite.^{70,71} Luckily, perovskite materials show a large carrier path and PSCs can also work without the HTM.^{72,73} In this architecture, an insulating layer, such as Al_2O_3 or ZrO_2 , is necessary to keep the front electrode separated from the back one.⁷⁴

To date, the best performances have been obtained with gold as the back electrode. However, the noble element may be replaced by carbon-based materials, such as graphite, graphene, CNTs and so on. In fact, carbon has a suitable work function of 5.0 eV, very close to that of gold (5.1 eV).²⁹ In addition, carbon-based materials are processable, highly conductive, thermally inert and hydrophobic.⁷⁵ Carbon-based back electrodes represent a concrete and indispensable strategy towards the large-scale industrial production of PSCs. Fig. 1 shows that it took 4 years, from the first reported perovskite-based PVs (2009), to see the first articles published on this topic. However, it must also be specified that all articles on PSCs published before 2012 were focused on devices using liquid electrolytes. Carbon-based devices appeared approximately only one year after the first solid-state PSC based on spiro-OMeTAD. As well known, the unexpected efficiency improvement that spiro-OMeTAD promoted is sometimes considered the true starting point of the PSC topic. To date, publications on carbon-based PSCs count for about 10% of the overall PSC articles, maintaining an upward trend after 2015.

Among the most known compounds, graphite is a soft material, composed of a hexagonal lattice layer, with high electrical conductivity and excellent thermal stability. On the other hand, CB is an amorphous nanopowder obtained by incomplete combustion of carbonaceous materials.⁷⁵ Even though it shows lower conductivity than graphite, carbon black is used to distort and break the preferential orientation of graphite flakes. Indeed, a full graphite layer would not ease the infiltration of the perovskite solution. Furthermore, it must

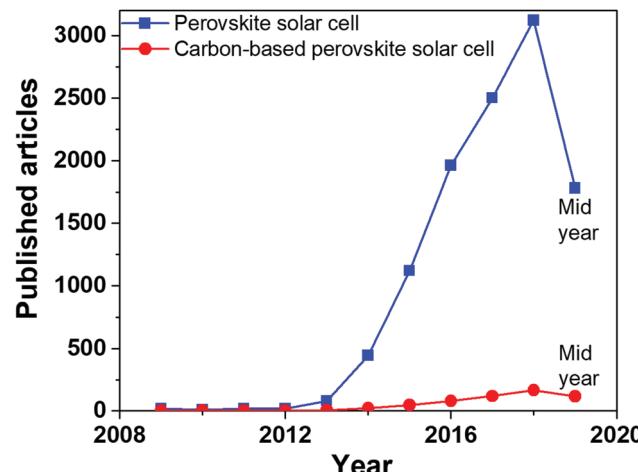


Fig. 1 Published articles from 2009 to 2019 on "perovskite solar cells" and "carbon-based perovskite solar cells". Data extracted from Scopus database on 30th June 2019.

also be stressed that the ratio between carbon black and graphite is relevant not only in terms of electrical conductivity; conversely, it also has an influence on the processability of the carbon paste, in terms of viscosity, adhesion to the other cell layers and infiltration degree of the perovskite.^{76,77}

Carbon-based materials may be processed by two main deposition techniques. The first process requires temperatures in the range 400–500 °C.⁵⁸ A mesoporous carbon layer is deposited by doctor-blade or screen-printing techniques on the top of an insulating layer, and subsequently sintered. The insulator has the role of preventing the contact between the front and the back electrode, thus avoiding photocurrent leakage. To the best of our knowledge, three oxides have been successfully used as insulating layers in the PSC field: ZrO_2 ,^{78,79} Al_2O_3 ^{79,80} and TiO_2 .⁸¹ The latter can be used both as a compact layer and as a mesoscopic layer, in combination with ZrO_2 and Al_2O_3 .⁸¹ Generally speaking, ZrO_2 is more efficient as the insulating layer with respect to Al_2O_3 . In fact, its larger pores facilitate the infiltration of the perovskite phase and its contact with the anodic material.⁷⁹ The effect of the thickness of the insulating layer has been investigated by Liu *et al.*⁷⁸ and Barichello *et al.*⁸⁰ Optimal thicknesses of 1 μm and 1.8 μm for ZrO_2 and Al_2O_3 , respectively, were found. Below these values, most of the generated photoelectrons recombined with holes, leading to a high energy loss. On the other hand, the thickness of the insulating layer should not be higher than the limit of carrier diffusion length. More details on this topic can be found in a recently published review article.⁸²

The perovskite phase is formed later, since it is not stable over 120 °C,⁸³ by drop-casting a precursor solution on top of the carbon layer. The perovskite precursor solution must penetrate the entire thickness of the carbon layer, to ensure a contact with the anode. Mesoscopic cells, where a good interface between carbon and the perovskite is established, are obtained by this strategy. However, the penetration is somehow difficult, may require the use of additives and is not applicable to flexible

substrates. The other strategy is a layer-by-layer deposition,⁵⁸ where a perovskite phase is formed by a one- or two-step method and carbon is doctor-bladed or screen-printed on top of $\text{CH}_3\text{NH}_3\text{PbI}_3$ or HTM. The carbon layer may also be deposited on another substrate and then transferred onto the cell. These depositions are simpler, do not require high temperature and may be suitable also for flexible devices, but the interface usually suffers from poor contact.^{84–86} Planar architectures with and without HTMs are obtained.

The most significant and state-of-the-art outcomes on these two families of processing strategies of graphite- and carbon black-based back electrodes are reviewed in the forthcoming sub-sections.

2.1 High-temperature processed front electrodes

In 2013, Ku *et al.* reported the first use of carbon black/graphite as a back electrode in a PSC.²⁹ Exploiting the ambipolar charge transfer properties of perovskites, a HTM was not used. Instead, an insulating ZrO_2 layer was put on top of the TiO_2 layer to prevent contact between the front and back electrodes. To further improve the device performances, spheroidal graphite with better conductivity and favorable morphology for pore filling was used in the carbon composite electrode. As evidenced by cross-sectional scanning electron microscopy (SEM) images, shown in Fig. 2, a more effective pore filling was ensured by the smooth structure of spheroidal graphite. In fact, the PCE was improved from 4.08% to 6.64%. The stability dropped only by

2% from the initial value after 70 days, confirming the positive role of the hydrophobic carbon layer in preventing the perovskite phase from the penetration of water molecules.

The influence of both carbon layer thickness and graphite size on the cell PCE was investigated by Zhang *et al.* in 2015.⁸⁷ In fact, if the carbon layer is too thick, the penetration of the perovskite precursor solution is hindered. As a consequence, a poor contact between carbon and the perovskite phase is established. However, too thin carbon layers do not provide sufficient conductivity. The carbon layer thickness ranged from 5 to 15 μm and it was found that the optimal thickness was 9 μm , with a short-circuit current density (J_{sc}) of 18.06 mA cm^{-2} and a remarkable PCE of 11.63%. On the other hand, graphite flakes with different sizes were added to the carbon paste, to further enhance the conductivity of the carbon back electrode. Dimensions of graphite flakes ranged from 0.5 to 8 μm ; it was found that the 8 μm -large sample ensured the best perovskite infiltration, having the biggest pore size. In addition, it had the lower square resistance.

Different results were obtained by Raminafshar *et al.* in 2018.⁸⁸ They investigated the effect of TiO_2 , ZrO_2 and carbon thickness in HTM-free, high-temperature processed PSCs. Concerning the back electrode, the carbon layer should be thin enough to ensure perovskite infiltration; however, too thin layers are mechanically fragile and can crack, with a drop in the conductivity. Four thickness values were tested: 6.5, 15, 25 and 54 μm . On the other hand, the thicknesses of TiO_2 and ZrO_2 were kept constant at 0.4 and 1.7 μm , respectively. As reported in Table 1, the PCE improved with carbon thickness. Only when the layer became too thick (54 μm) the PCE dropped due to the poor penetration of the perovskite phase. The best carbon thickness was 25 μm , with an open-circuit voltage (V_{oc}) of 0.88 V, a J_{sc} of 21.4 mA cm^{-2} , a fill factor (FF) of 0.57 and a PCE of 10.7%.

It is matter of debate in the scientific community if the carbon layer behaves simply like an electrode ohmic contact or has HTM properties. Indeed, carbon shows a higher work function than other commonly used metals, such as silver and aluminium, and its Fermi level (-5.0 eV) is close to the VB maximum of $\text{CH}_3\text{NH}_3\text{PbI}_3$ (-5.4 eV). This makes the hole extraction at the perovskite/carbon interface possible and paves the way to HTM-free PSCs. In the last six months, the origins of subgap tail states and V_{oc} were investigated by Du *et al.*, and the main outcome was that the cell voltage was more affected by the perovskite crystallinity than by other factors.⁸⁹ Gelmetti *et al.* studied the energy alignment and recombination in PSCs

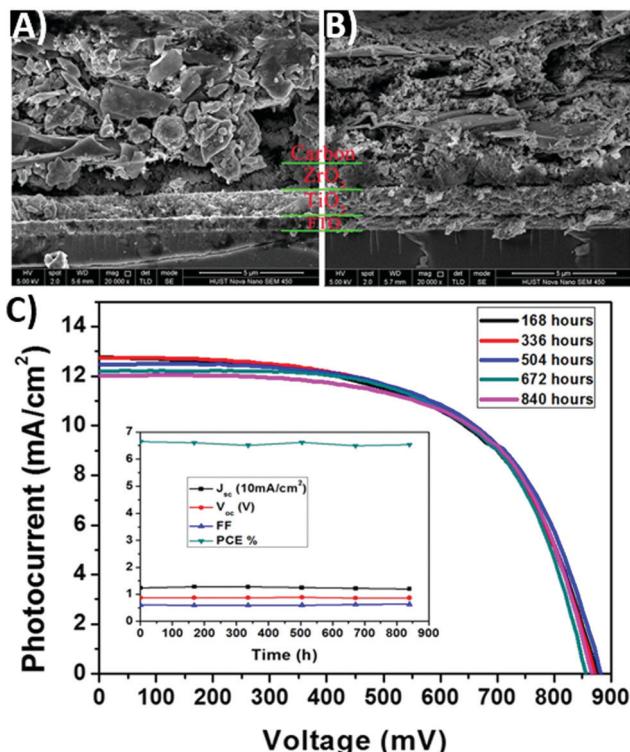


Fig. 2 Cross-sectional SEM images of (A) a spheroidal graphite-based cell and (B) a flake/bulk graphite-based device. (C) Long-term stability of PSCs at room temperature in the dark. Adapted and reprinted with permission from ref. 29.

Table 1 PV parameters of carbon-based PSCs fabricated with back electrodes bearing different thicknesses. Adapted and reprinted with permission from ref. 88

Thickness (μm)	Series resistance (Ω)	V_{oc} (V)	J_{sc} (mA cm^{-2})	FF	PCE (%)
6.5	169	0.85	10.3	0.53	4.6
15	120	0.86	12.7	0.54	5.9
25	56	0.88	21.4	0.57	10.7
54	41	0.67	14.3	0.45	4.3



by choosing HTMs with close chemical and physical properties; however, once they were deposited on the perovskite layer, different performance characteristics were obtained with respect to those predicted.⁹⁰ In particular, upon deposition on top of the perovskite, an important change in the energy level position was detected. From some recent reports and communications to relevant conferences, it has often been hypothesized that the HOMO and VB matching between the HTM and hybrid perovskite is almost irrelevant to achieve high V_{oc} in PSCs. This is quite a disruptive topic, especially when considering that just a couple of years ago the lower V_{oc} of carbon-based HTM-free PSCs was motivated by the absence of a standard HTM compound in the cell.⁵⁸ Indeed, if V_{oc} is determined by the difference between the electron quasi-Fermi level (e.g., ETM/TiO₂ interaction) and the hole quasi-Fermi level (e.g., perovskite/HTM interaction), after removing the HTM the latter level should be determined by the perovskite/carbon interaction, which will lift the level position due to the higher Fermi level of carbon than the HOMO of common HTMs. As a result, V_{oc} of carbon-based HTM-free PSCs was supposed to be lower than that of HTM-based cells and lowering the Fermi level of carbon electrodes was considered as a milestone to increase the cell potential. Even if the scope of this review is not that of investigating the origins of V_{oc} in PSCs, the reader is invited to consider this point when checking the solar cell parameters of carbon-based HTM-free devices.

Another important parameter to consider is the temperature of the annealing process. In fact, it can influence both morphologic and electrical properties of the carbon electrode. In 2019, Mishra *et al.* studied the effect of annealing temperature in carbon electrodes deposited by the screen-printing of commercial carbon pastes.⁹¹ It was found out that temperatures below 300 °C did not lead to working PSCs. In fact, high-temperature sintering ensured a better contact between particles, thus allowing a faster charge transfer and higher conductivity. The evaporation of organic solvents was facilitated by the use of high temperature. In this way, a highly mesoporous structure, with pore filling ability, was created. On the other hand, highly resistive electrodes, with poor perovskite infiltration, were formed at temperatures lower than 300 °C. The samples treated at 350 and 400 °C achieved a remarkable PCE of 8.4% and 12.4%, respectively. SEM images showed an increased uniformity and a defect-free morphology in high-temperature treated carbon films. Raman spectra underlined the high graphitization degree and the lack of defect regions.

Besides thermal treatment, another efficient solution to improve the charge extraction ability of the carbon back electrode was proposed by Tian *et al.* in 2018.⁹² They suggested that a fine regulation of the oxygen content in the carbon black, used to fabricate the back electrode, may be exploited for tuning the work function of carbon and increasing the surface area and the contact with the perovskite phase. Oxygen can be considered as a dopant, since it increases the work function of the material; it can be present as C-OH, COOH and C=O groups on the surface, enlarging the interlayer distance through electrostatic repulsion, thus increasing the surface area. Two samples, with a high (oxygen rich carbon – ORC) and low (oxygen deficient carbon – ODC)

content of oxygen-containing groups, were prepared. Brunauer–Emmett–Teller (BET) analysis highlighted the increased surface area of ORC with respect to ODC (186.4 vs. 112.5 m² g⁻¹, respectively). Cross-sectional SEM of ODC showed particles with surface defects and pin-holes, whereas ORC was present in the form of particles entrapped in the perovskite phase, thus ensuring an effective contact with the active material. The improved properties of ORC reflected also on the PV results. In fact, V_{oc} increased from 0.88 to 0.98 V, J_{sc} from 22.98 to 23.20 mA cm⁻², FF from 67.2 to 69.1 and PCE from 13.59 to 15.70%.

A highly interconnected carbon can also be obtained starting from natural biomass, treated at high temperatures. In fact, natural organisms are rich in interconnected biomolecules with high molecular weight, and the dense and interconnected structure can be maintained even after the thermal treatment. For example, in 2018 Mali *et al.* reported, in an interesting work, a carbon material derived from an *Aloe Vera* plant (AV-C), used as a back electrode for PSCs.⁹³ The *Aloe Vera* gel was extracted from the leaves and dried under sunlight, forming a black powder. Then, the product was washed with HCl and treated at very high temperature (1000 °C). The resulting material presented highly interconnected nanoparticles with dimensions of 40–45 nm, as confirmed by SEM and transmission electron microscopy (TEM) techniques, and a graphitic structure with sp² carbon, as demonstrated by X-ray diffraction (XRD) and Raman analysis (see Fig. 3). When used in PSCs with ZrO₂ as an insulator, AV-C provided a PCE of 12.58% and quite good stability: indeed, it retained 85% of the initial efficiency after 1000 h.

High-temperature processed carbon may suffer from poor contact with the perovskite phase in mesoscopic PSCs. In fact, bulk graphite has a large grain size, with small specific surface area. However, to ensure a good contact with the perovskite phase, a material with large surface area and interconnected channels is required. For this reason, malleable ultrathin graphite (UG) was used instead of bulk graphite (BG) for the first time by Duan *et al.* as a cathode material for PSCs.⁹⁴ UG was prepared by mechanical exfoliation of BG and mixed with carbon black. The latter is a fine carbonaceous powder, with small particles, that breaks the extremely oriented and impermeable graphite layer, improving infiltration phenomena. As confirmed by SEM images shown in Fig. 4A–D, although particle dimensions of BG and UG were similar, UG had a more malleable morphology, better suited for the perovskite phase, and that ensured an effective pore filling of the precursor solution. In addition, the specific surface area of UG (202.24 m² g⁻¹) was remarkably higher than that of BG (69.01 m² g⁻¹). A UG-based cell resulted mostly in higher FF (V_{oc} = 901 mV, J_{sc} = 22.97 mA cm⁻², FF = 0.68, PCE = 14.07%) with respect to that of the BG-based one (V_{oc} = 893 mV, J_{sc} 22.89 mA cm⁻², FF = 0.62, PCE = 12.63%), measured with reverse scan direction.

Another strategy for improving the contact of carbon with perovskites is the use of a volatile, pore forming agent in carbon pastes. When the carbon paste is deposited and thermally treated, this agent decomposes and leaves pores that facilitate the penetration of the perovskite precursor solution into the



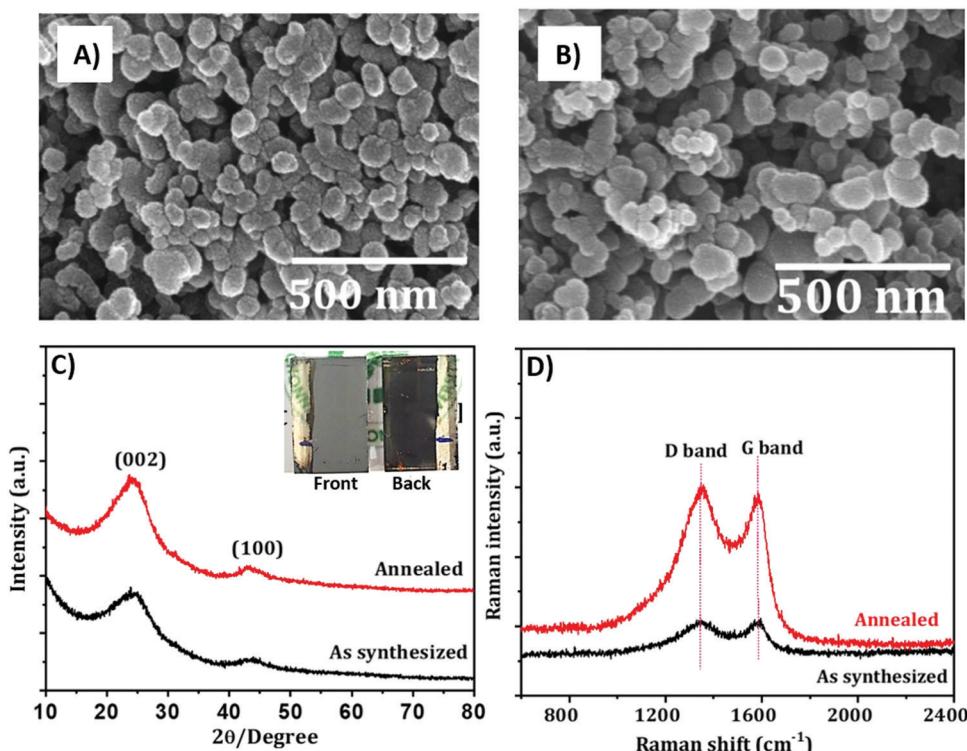


Fig. 3 SEM images of the extract from the Aloe Vera plant (A) before and (B) after annealing. (C) XRD and (D) Raman spectra of the extract before and after annealing. The inset in (C) shows optical images of Aloe Vera-derived PSCs from both front and back views. Adapted and reprinted with permission from ref. 93.

mesoporous structure. In 2018, Tao *et al.* used different contents of polystyrene spheres (PSSs) as pore forming agents in carbon pastes, in order to obtain a highly porous carbon back electrode for PSCs.⁹⁵ Fig. 4E shows the pristine material, deposited by screen-printing. Fig. 4F shows the PSSs-10% carbon paste before annealing, with PSSs clearly visible on the surface. After the thermal treatment, PSSs were removed, leaving a highly porous material, as shown in Fig. 4G. The weight ratio of PSSs with respect to the carbon paste had an effect on the PCE of the resulting devices. In fact, the optimal percentage was 10%, with a V_{oc} of 782 mV, a J_{sc} of 9.32 mA cm⁻², a FF of 0.56 and a PCE of 4.10%; these values were improved with respect to those of the pristine material (V_{oc} = 704 mV, J_{sc} of 8.36 mA cm⁻², FF = 0.55 and PCE = 3.36%). A further increase in the PSSs content brought to a reduced PCE of 3.13%, mainly due to the decreased conductivity of the carbon electrode.

One of the main issues with carbon-based PSCs is the high resistance of the cell and the uncontrolled crystallization of the perovskite phase in the porous stack. An attempt to reduce the sheet resistance and ameliorate interfaces between printed stacks was made by Hashmi *et al.* in 2017.⁹⁶ They reported a humidity-assisted thermal exposure (HTE) as a post-treatment method for PSCs. After the pore filling of the substrate with the perovskite precursor solution (one-step deposition method), the cell was exposed to 70% relative humidity (RH) for 115 h. This treatment resulted in a drastic enhancement of the preliminarily measured PV parameters. Also, the hysteresis effect was reduced. This beneficial effect may be ascribed to

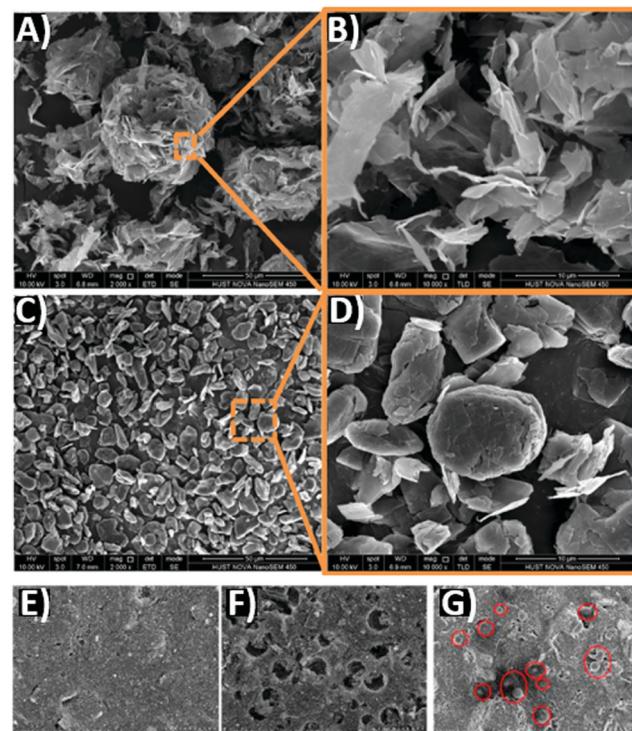


Fig. 4 SEM images at low and high magnification of (A and B) UG and (C and D) BG, highlighting that the UG sheets tend to stick together to form a fluffy agglomerate; UG has a diameter of 5–15 μ m, similar to BG. SEM images of (E) pristine carbon paste, (F) PSSs-10% carbon paste before and (G) after thermal treatment. Adapted and reprinted with permission from ref. 94 and 95.

two main factors: first of all, the sheet resistance of the carbon layer, measured by the four-probe sheet resistance method, was found to drastically reduce after the HTE treatment. Water molecules probably increased the interconnectivity between carbon nanoparticles (NPs) and perovskite crystals. Secondly, the hydrophobic carbon impeded the fast intrusion of water drops, that would have led to the decomposition of the perovskite, and allowed only the penetration of gaseous water molecules. Perovskite growth under humidity was already demonstrated by You *et al.*⁹⁷ Larger crystals, with an optimal contact with both anode and carbon layer, were obtained. One batch of devices was stored at 40 °C under full sun illumination and retained 92% of its initial efficiency after 350 h, confirming the irreplaceable role of hygroscopic carbon in preventing moisture penetration.

A suitable strategy to further enhance PSC efficiency is the replacement of a methylammonium (MA) cation⁹⁸ with 5-amino valeric acid (5-AVA)⁹⁹ or formamidinium ($\text{HC}(\text{NH}_2)_2^+$, FA).^{100,101} When 5-AVA is added in the precursor solution, it replaces the MA cation in the cuboctahedral site of MAPbI_3 . 5-AVA templates the crystallization of the perovskite in the pores of mesoporous TiO_2 , providing a lower defect concentration,⁹⁹ while its $-\text{COOH}$ and $-\text{NH}_2$ groups interact with TiO_2 through hydrogen bonding, ensuring a better interfacial contact with the anode.¹⁰² Mei reported an increase in PCE from 7.2% to 11.6% by replacing MA with 5-AVA,⁹⁹ while Santhosh reported an average PCE of 6.47% for the same cell (see Table 2).¹⁰² The lower PCE was ascribed to the poor FF, due to a non-optimal assembly of the cell. On the other hand, the FA cation forms a perovskite phase with a band-gap of 1.47 eV, lower than that of MAPbI_3 (1.55 eV). FAPbI_3 has a stronger absorption in the visible range with respect to MAPbI_3 , so it can convert light into electricity more efficiently. In 2014, Hu *et al.* for the first time incorporated FAPbI_3 into a carbon-based PSC.¹⁰⁰ The band alignment of FAPbI_3 with respect to the TiO_2 anode and carbon electrode was favorable for electron and hole injection, respectively, as shown in Fig. 5A. As a matter of fact, the J_{sc} slightly increased, passing from 17.5 to 18.4 mA cm^{-2} . On the other hand, the V_{oc} decreased, so the PCE was rather unchanged (see Fig. 5B). The mixed perovskite, with both cations, permitted attainment of higher J_{sc} and PCE values, as reported in Table 2.

A similar strategy was followed by Xu *et al.* in 2018.¹⁰³ Phenethylammonium iodide (PEAI) was introduced into the

Table 2 PV parameters of carbon-based PSCs bearing different cations in the light-absorbing layer. PCE shown in entry III is a certified value

Perovskite	V_{oc} (mV)	J_{sc} (mA cm^{-2})	FF	PCE (%)	Ref.
MAPbI_3	855	13.9	0.61	7.2	99
$(5\text{-AVA})_x(\text{MA})_{1-x}\text{PbI}_3$	843	21.1	0.65	11.6	99
$(5\text{-AVA})_x(\text{MA})_{1-x}\text{PbI}_3$	858	22.8	0.66	12.84	99
$(5\text{-AVA})_x(\text{MA})_{1-x}\text{PbI}_3$	830	15.6	0.49	6.47	102
MAPbI_3	928	17.5	0.70	11.4	100
FAPbI_3	901	18.4	0.72	11.9	100
$(\text{FA})_{0.6}(\text{MA})_{0.4}\text{PbI}_3$	921	20.9	0.67	12.9	100
MAPbI_3	900	11.41	0.60	6.30	103
$\text{PEA-}\text{MAPbI}_3$	900	16.12	0.60	8.68	103
CsPbBr_3 (mesoscopic)	1270	6.29	0.60	4.77	125
CsPbBr_3 (planar)	1330	5.09	0.55	3.67	125

perovskite precursor solution as an additive, as shown in Fig. 5C. Similar to 5-AVA, the phenethylammonium (PEA) cation improved the contact with TiO_2 at the interphase, ensured a better pore filling of the solution and lowered the defect concentration in the perovskite film. As a matter of fact, the crystallinity of the perovskite material increased and the film was adherent to the mesoporous TiO_2 . As demonstrated by time-resolved photoluminescence (PL) spectra,^{104,105} the exciton lifetime in $\text{PEA-}\text{MAPbI}_3$ was much longer (40 ns) with respect to that in MAPbI_3 (12 ns). $\text{PEA-}\text{MAPbI}_3$ also exhibited a stronger absorption than MAPbI_3 in the range 350–800 nm, as shown in Fig. 5D. These optimized properties resulted in a higher J_{sc} (from 11.41 to 16.12 mA cm^{-2} , see Table 2 and Fig. 5E), thus leading to a higher overall PCE.

The main problem associated with MA- and FA-based perovskites is the poor stability under air moisture and heat.^{106–110} For these reasons they require a strong humidity control (e.g., glovebox conditions) during the fabrication process and are not suitable for real outdoor conditions, where high temperatures can be easily reached.^{111–113} In order to increase their stability, the organic moiety may be partially or totally eliminated.^{114–116} Caesium(i) is a suitable large cation that can be easily incorporated into lead-based perovskites, both in mixed-cation perovskites^{117,118} and in fully inorganic CsPbI_3 perovskites.^{119,120} Despite a remarkable initial PCE of 10%,¹²¹ inorganic CsPbI_3 underwent an irreversible transformation toward a non-perovskite phase. Therefore, the stability was seriously compromised.^{121,122} However, the thermal stability can be increased by fully replacing iodide with bromide.^{123,124} In fact, CsPbBr_3 is stable till 580 °C¹²⁵ and presents great charge transport ability and mean free path.¹²⁶ This perovskite was used in planar PSCs and showed a remarkable stability for more than three months in humid air.¹²² For the first time, in 2018 Poli *et al.* demonstrated that CsPbBr_3 was able to work as an active material also in mesoscopic PSCs.¹²⁵ The mesoporous carbon layer was annealed at different temperatures, ranging from 100 to 400 °C. Samples annealed below 400 °C still presented traces of organic binder present in carbon pastes. Only for the sample annealed at 400 °C a pure perovskite phase was found. The PV parameter that was mostly influenced by temperature was the V_{oc} . In fact, the presence of other species can truly influence the recombination rate.^{127,128} The optimal annealing temperature was 400 °C, and the corresponding devices showed an average V_{oc} of 1.27 V, a J_{sc} of 6.29 mA cm^{-2} , a FF of 73.5 and a PCE of 4.77% (see Table 2). For comparison, an analogous planar architecture was also reported, which presented a lower PCE (3.67%), even if the V_{oc} was higher (1.33 V) as shown in Table 2. This was ascribed to the fact that high-temperature treated mesoporous carbon presented high roughness, which allowed the permeation of the precursor solution and ensured a more effective contact with the perovskite phase, with respect to the planar carbon layer.

TiO_2 is the most used anodic material not only for PSCs, but also for dye-sensitized solar cells (DSSCs).^{129–141} It presents several advantages, such as low cost, low toxicity, adequate band-gap and high electron collection efficiency. Some efforts have been made to further ameliorate its performance in



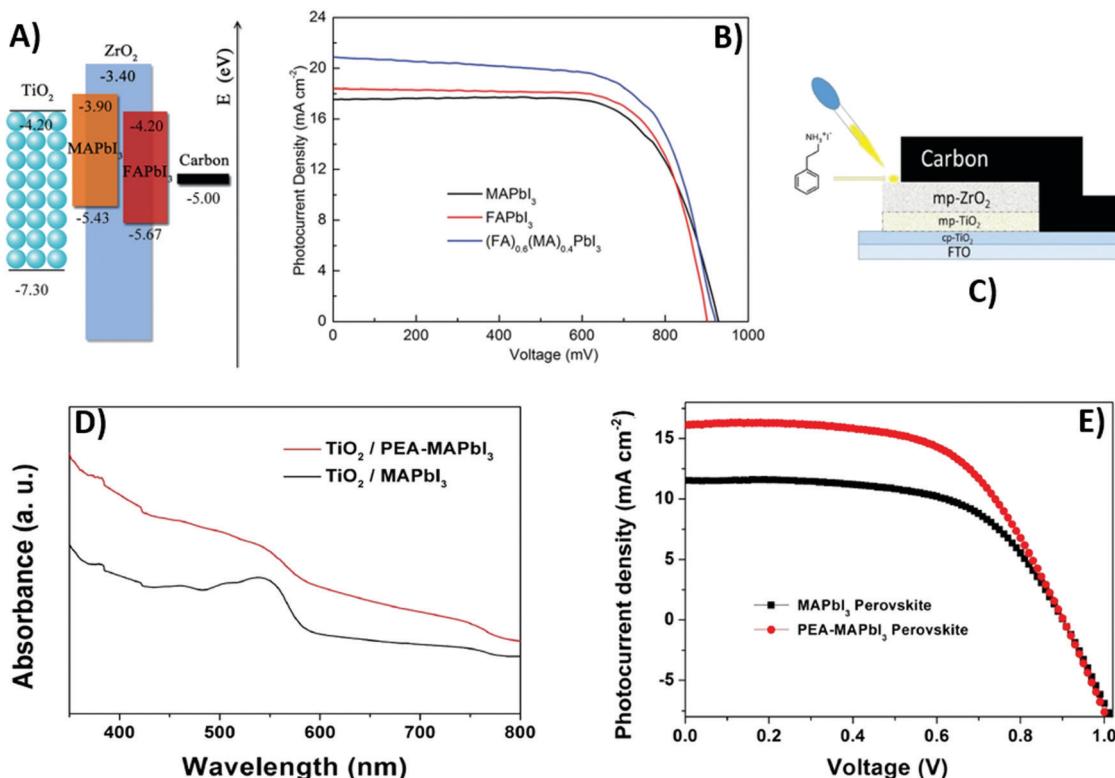


Fig. 5 (A) Band alignment of MAPbI_3 and FAPbI_3 perovskites with respect to TiO_2 and carbon. (B) J – V curves of MAPbI_3 -based (black), FAPbI_3 -based (red) and $(\text{FA})_{0.6}(\text{MA})_{0.4}\text{PbI}_3$ -based (blue) cells. (C) Device configuration of fully printable MAPbI_3 - and PEA- MAPbI_3 -based PSCs, and a comparison of their (D) absorption spectra and (E) J – V curves. Adapted and reprinted with permission from ref. 100 and 103.

carbon-based PSCs. In 2014, Rong *et al.* synthesized TiO_2 nanosheets (NSs) by a hydrothermal route in hydrofuran solution, and compared the resulting PCE with that of TiO_2 NPs.¹⁴² The structure of TiO_2 NSs ensured a higher number of (001) facets, with respect to that observed for TiO_2 NPs, due to the elongated geometry. It was found that the (001) anatase facet was slightly more reactive than the (101) counterpart because of the larger number of titanium atoms without coordination.¹⁴³ In addition, the (001) facet presented a higher charge density, that may strengthen the interaction with the active absorbing material. Consequently, electron injection was facilitated.^{144,145} As shown in J – V curves (see Fig. 6A), V_{oc} , J_{sc} and PCE of the NSs-based device were higher than those of the NPs-based one (868 mV, 20.1 mA cm^{-2} and 10.64% vs. 839 mV, 13.7 mA cm^{-2} and 7.36%); a TEM image of NSs is shown in Fig. 6B.

Similar results were obtained by Zhang *et al.* in 2018.¹⁴⁶ They built two types of 1 μm -thick anodes, one based on TiO_2 NSs (see Fig. 6D) and the other one based on TiO_2 NPs. The PCE of the NS-based device shown in Fig. 6C was almost twice that of the NP-based one (8.11% vs. 4.37%, respectively), confirming that the (001) anatase facet was more reactive and suitable for perovskite adhesion and electron injection. In addition, they varied the TiO_2 layer thickness from 0.3 to 1.4 μm , and found that the best results were provided by 1 μm -thick TiO_2 . In fact, recombination decreased by increasing the layer thickness, as confirmed by electrochemical impedance spectroscopy (EIS)

analysis.¹⁴⁷ However, a too thick TiO_2 layer caused high series resistance.

Another strategy used to ameliorate the anode performances is the surface modification of TiO_2 . In 2015, Liu *et al.* reported a HTM-free PSC with an organic silane self-assembled between TiO_2 and the perovskite.¹⁴⁸ The silanization of the anode was achieved by dipping a high-temperature processed $\text{TiO}_2/\text{ZrO}_2/\text{carbon}$ substrate and subsequent hydrolysis. This extra layer drastically reduced recombination processes at the interphase between the perovskite and TiO_2 , as confirmed by the drastically increased recombination resistance in the EIS spectrum. PCE values were determined as a function of silane treatment time. Efficiencies of 9.71%, 11.10%, 12.41%, 12.77% and 10.44% were reached with treatment times of 0, 0.5, 1, 4 and 24 h, respectively. Therefore, the PCE increased with treatment time, till a maximum of 4 h. After that, an excess of silane on the TiO_2 surface caused poor infiltration of the perovskite precursor solution.

In order to replace expensive HTMs, many p-type inorganic semiconductors have been reported. Among them, NiO showed several advantages, such as low cost, stability, wide band-gap and high hole mobility.¹⁴⁹ In 2015, Cao *et al.* used NiO as the HTM and reported a $\text{TiO}_2/\text{Al}_2\text{O}_3/\text{NiO}/\text{carbon}$ architecture with infiltrated perovskite precursor solution, as shown in Fig. 7A.¹⁵⁰ All layers were deposited by the screen-printing method, ensuring a reproducible and scalable procedure. NiO successfully increased the PV efficiency. As a matter of fact, the PCE

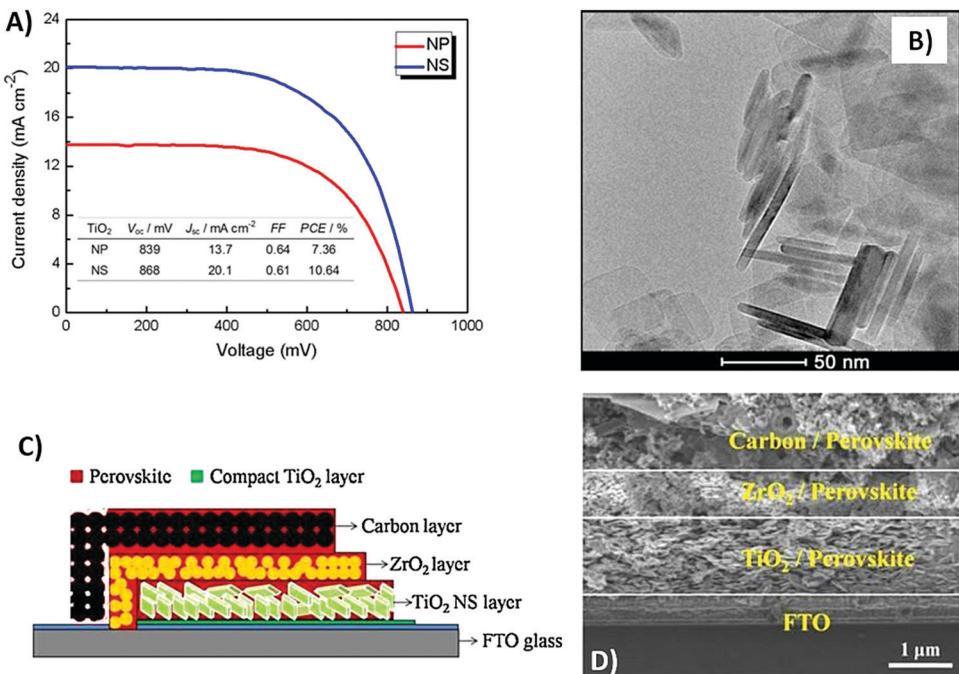


Fig. 6 (A) $J-V$ curves of NPs- and NSs-based PSCs under AM 1.5 simulated sunlight of 100 mW cm^{-2} and, in the inset, the corresponding PV parameters; (B) TEM images of TiO_2 NSs. (C) Schematic structure of a PSC with a 4-layer structure, bearing the perovskite infiltrated through the carbon electrode; (D) cross-sectional field emission SEM (FESEM) image of a PSC where a TiO_2 NS layer and the carbon electrode are separated by a ZrO_2 layer to avoid direct contact. Adapted and reprinted with permission from ref. 142 and 146.

increased from 11.20% (for the NiO-free PSC) to 15.03% (for the NiO-containing PSC). It was suggested that NiO limited charge recombination and ameliorated hole collection efficiency toward the carbon electrode.

A similar architecture was reported in the same year by Xu *et al.*¹⁵¹ ZrO_2 was used as both spacer and insulator to keep the TiO_2 anode and NiO semiconductor separated. The resulting $\text{TiO}_2/\text{ZrO}_2/\text{NiO}/\text{carbon}(\text{MAPbI}_3)$ architecture presented a p-i-n configuration as shown in Fig. 7B and C. Besides enhancing charge collection at the interface with the carbon back electrode, NiO successfully acted also as an electron blocking layer, thus reducing charge recombination. As a matter of fact, the device with this architecture attained remarkably high photovoltaic performances, with a V_{oc} of 917 mV, a J_{sc} of 21.36 mA cm^{-2} , a FF of 0.76, an average PCE of 13.7% and a maximum PCE of 14.9%. Long-term stability of the device was confirmed, since at room temperature and at 40% RH it retained 93% of the initial PCE after 1000 h of aging under dark conditions. The device was not sealed; in fact, hydrophobic carbon can prevent atmospheric moisture from penetrating the perovskite layer.

Charge transport in NiO can be attributed to positively-charged nickel vacancies. By increasing the temperature, the removal of some nickel(II) cations results in increasing the number of oxygen atoms surrounding the remaining nickel atoms. For this reason, some nickel(II) are oxidized to nickel(III) and conductivity is attributed to hole hopping from the Ni^{3+} sites to Ni^{2+} ones. To further enhance charge mobility, NiO can be treated with ultraviolet (UV)/ O_3 and annealed at high temperature. The UV/ O_3 treatment generates NiOOH species on

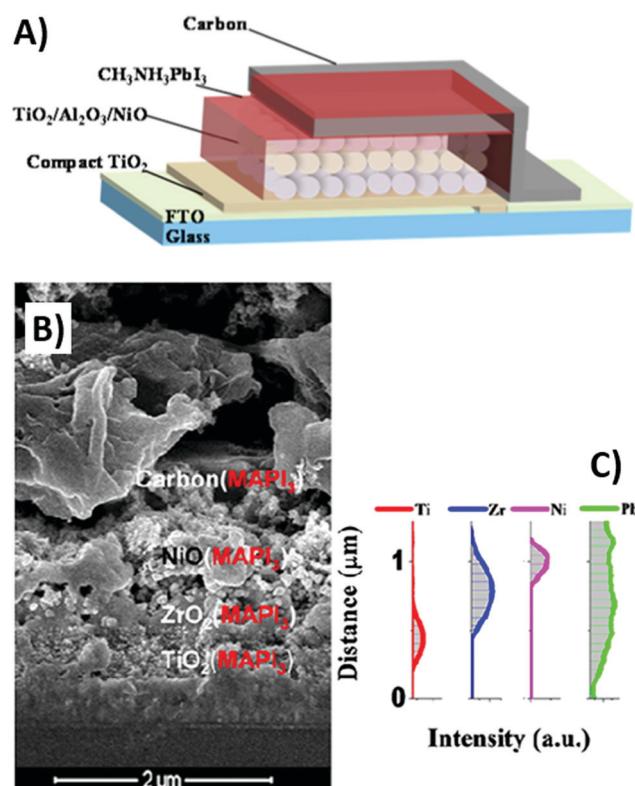


Fig. 7 (A) A carbon-based PSC architecture composed of four printed layers. (B) Cross-sectional SEM of $\text{TiO}_2/\text{ZrO}_2/\text{NiO}/\text{carbon}(\text{MAPbI}_3)$ and (C) atomic distribution obtained by energy dispersive X-ray (EDX) analysis. Adapted and reprinted with permission from ref. 150 and 151.

the surface of nickel oxide. Hydroxyl groups are then removed by thermal treatment. Ni_2O_3 with a low transport resistance and a high charge mobility is formed. This treatment has been used by Behrouznejad *et al.* to provide a mesoscopic PSC with a NiO /carbon back electrode.¹⁵² When a 450 nm-thick Al_2O_3 space layer was used, an average PCE of 11.28% (with best device having a PCE of 12.12%) was achieved. However, a drop in PCE of 18.2% was observed after three months.

Aside from NiO , other transition metal oxides were taken into account as the HTM for PSCs.¹⁵³ However, it was found out that only NiO had a positive effect on PV parameters. In fact, MoO_3 , Co_2O_3 and CuO did not ensure an efficient interaction with the perovskite phase and the PCEs of the corresponding devices were quite lower than those of NiO -based devices: 0.82%, 6.93%, 6.08% and 13.94%, respectively.

Besides using NiO as the HTM, heteroatomic doping of graphite may be a suitable strategy for modifying the work function of carbon electrode and facilitating charge extraction.^{154,155} In fact, the tiny difference between the work function of carbon and the valence band of perovskite causes a carrier extraction barrier at the interphase, limiting PV performances. Carbon atoms in the graphitic layers can be easily replaced by electron-deficient boron by high-temperature thermal treatment with B_4C , as shown in Fig. 8A.^{156,157} After this treatment, the work function of the carbon electrode was improved by the incorporation of the electron-deficient boron atom (5.10 vs. 4.81 eV of pure graphite, PG). In addition, boron-doped graphite (BdG) showed

a lower sheet resistance (16 vs. 35 $\Omega \text{ sq}^{-1}$ of the PG). This was attributed to a better graphite layer packing and higher graphitization degree, as confirmed by XRD patterns. BdG-based devices showed improved V_{oc} , FF and PCE with respect to PG-based cells (940 mV, 0.63 and 13.6% vs. 900 mV, 0.60 and 12.4%, respectively). The increased FF and reduced hysteresis effect were ascribed to the more favorable band alignment in BdG-cells.¹⁵⁷

Other alternatives to NiO are p-type spinel oxides that are promising HTMs due to their excellent hole mobility. The first use of p-type Co_3O_4 as the HTM in carbon-based PSCs was reported in 2018 by Bashir *et al.*¹⁵⁸ Co_3O_4 has a cubic structure with high spin $\text{Co}(\text{II})$ in the tetrahedral sites and low spin $\text{Co}(\text{III})$ in the octahedral sites. In addition, the Co_3O_4 VB (-5.3 eV) matches well with that of perovskite (-5.4 eV), favoring efficient hole extraction. The effective contact between the perovskite and cobalt oxide and the improved hole extraction at the carbon electrode were demonstrated by the negligible hysteresis effect and by a high PCE of 13.27% ($V_{\text{oc}} = 0.88$ V, $J_{\text{sc}} = 23.43$ mA cm^{-2} , FF = 0.64).

Despite their dark appearance, carbon-based materials can also be used as transparent electrodes, necessary for semitransparent solar cells.¹⁵⁹ An ideal transparent electrode should exhibit high transparency, low resistance and charge collection efficiency. In this view, a thick layer of carbon-based materials may be the ideal candidate. Graphene and CNTs have already been successfully applied as back electrodes in semitransparent PSCs.^{160,161} However, in most cases, they are still prepared by

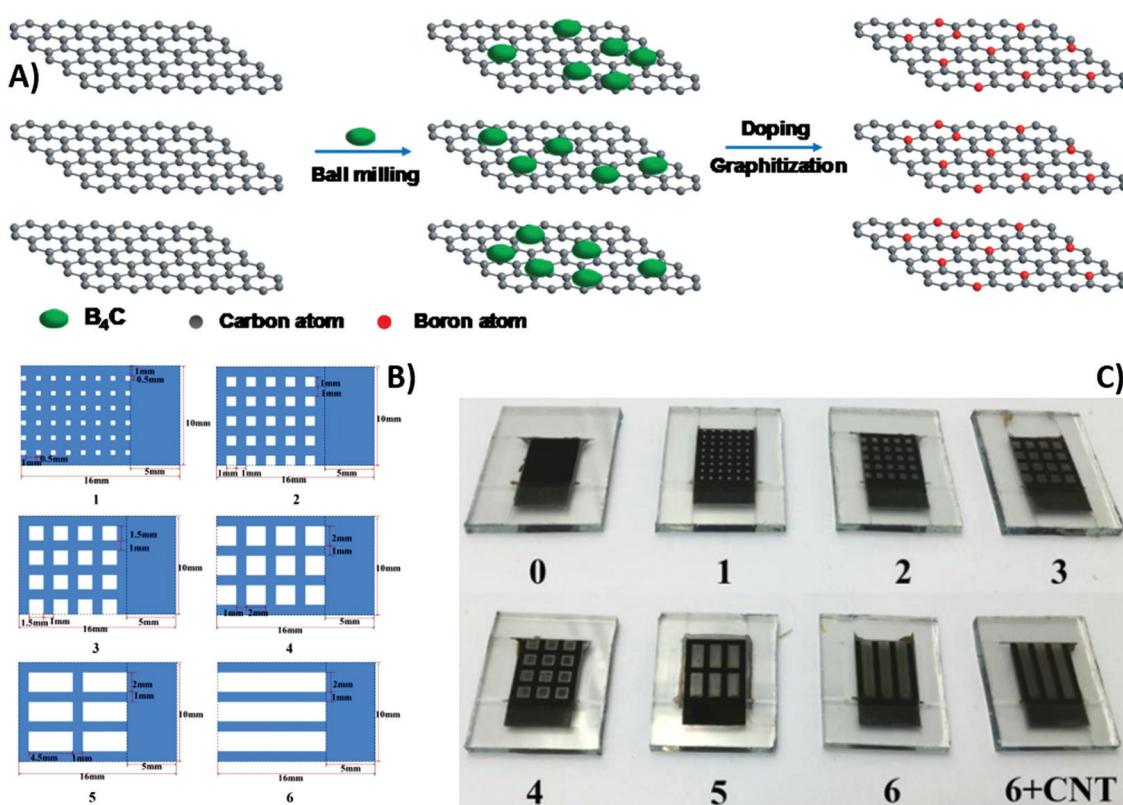


Fig. 8 (A) Preparation of BdG starting from graphite and B_4C . (B) Schematic diagrams of carbon back electrodes with different carbon grids (blue represents carbon), and (C) optical images of as-fabricated semitransparent PSCs. Adapted and reprinted with permission from ref. 157 and 162.



Table 3 Performance of devices based on different carbon back electrodes, with 10 devices being tested for each type of cell, in the work published by Li *et al.*¹⁶² Adapted and reprinted with permission from ref. 162

Device	V_{oc} (V)	J_{sc} (mA cm^{-2})	FF (%)	PCE (%)
0	0.85	20.16	52.5	9.00
1	0.87	21.07	58.9	10.80
2	0.85	20.21	53.6	9.21
3	0.85	18.87	53.8	8.63
4	0.85	16.66	56.3	7.97
5	0.84	13.97	51.3	6.02
6	0.84	11.32	53.4	5.08
6 + MWCNTs	0.87	17.94	51.5	8.04

non-scalable procedures, such as transferring and lamination. For these reasons, in 2017 Li *et al.* reported for the first time a fully printable carbon-based PSC with a $\text{TiO}_2/(5\text{-AVA})_{0.05}(\text{MA})_{0.95}\text{PbI}_3/\text{Al}_2\text{O}_3$ /carbon architecture.¹⁶² The carbon layer was deposited by the screen-printing method, using several grids with different geometries, as reported in Fig. 8B and C. For comparison, a carbon-based PSC without grid lines was also fabricated (device 0). Device 1 showed the best performances, even when compared to device 0, with a V_{oc} of 0.87 V, a J_{sc} of 21.07 mA cm^{-2} , a FF of 58.9% and a PCE of 10.80% (Table 3). This result was due to the fact that the smaller grid lines of device 1 ensured a better pore filling of the perovskite precursor solution. The decreased PCE with increasing number of grid lines was ascribed to the increase in series resistance of the electrode. To solve this issue, MWCNTs were coated on top of device 6. MWCNTs enhanced conductivity by creating a charge transport network. In fact, the PCE dramatically increased from 5.08% to 8.04%.

Further issues for the realization of scalable high-temperature processed carbon-based PSCs are (i) mechanical infiltration of the perovskite solution, in order to have a fully reproducible and printable fabrication method;¹⁶³ (ii) long-term stability under UV-light soaking;^{164,165} (iii) high-temperature thermal stability;¹⁶⁶ and (iv) enlargement of the active area of the cell.¹⁶⁷ The manual infiltration of the perovskite precursor solution onto the carbon layer limits reproducibility and is also time-consuming. For this reason, Hashmi *et al.* reported in 2017 a suitable strategy for the inkjet infiltration of the perovskite ink in HTM-free carbon-based PSCs.¹⁶³ The precursor ink was loaded into a disposable cartridge and deposited by an inkjet printer on the high-temperature processed carbon electrode. 5-AVA iodide was added in the precursor ink to slow down perovskite crystal growth, thus preventing the inkjet printer cartridge from clogging and ensuring a better filling through the carbon layer. In particular, $10 \times 10 \text{ cm}^2$ fluorine-doped tin oxide (FTO)-glass substrates having 18 individual cells of HTM-free triple layer PSCs were fabricated, as shown in Fig. 9A. Photovoltaic parameters showed improved reproducibility, with average values of 0.845 V (V_{oc}), 15.2 mA cm^{-2} (J_{sc}), 0.635 (FF) and 8.15% (PCE). PCE of the devices stored under dark conditions was found to initially increase by 13% in the first three weeks. This was ascribed to a further curing of the perovskite phase. Then, the PCE restored to its initial value and remained stable for 1046 h. On the other hand, the stability under sunlight soaking conditions at 35 °C was also determined. In this case, after 1046 h, the drop in PCE was

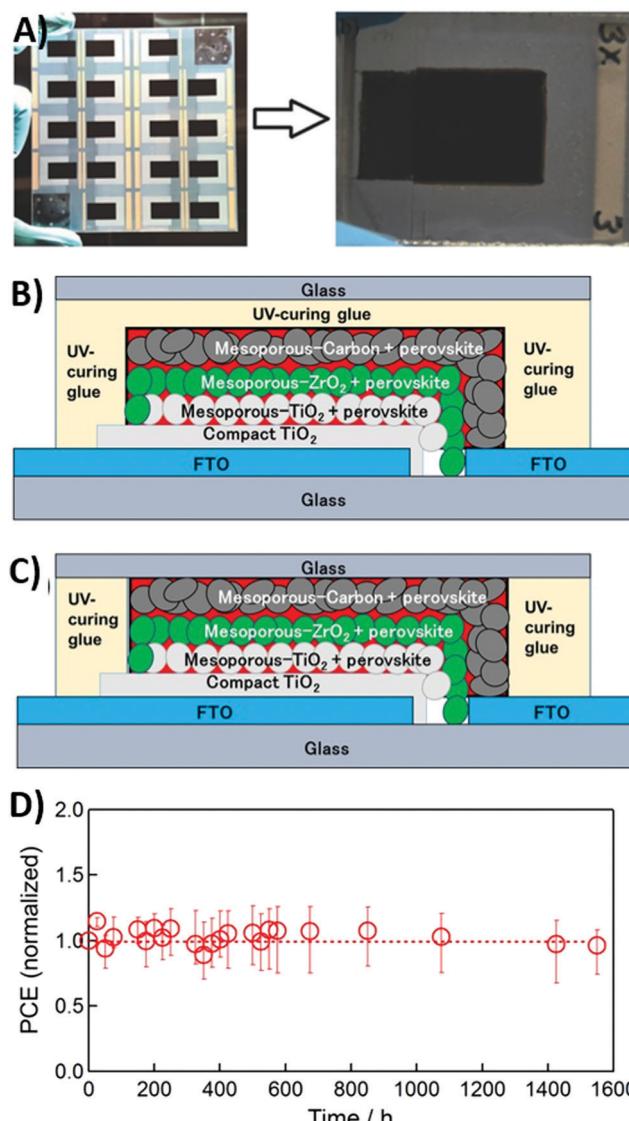


Fig. 9 (A) A $10 \times 10 \text{ cm}^2$ FTO-glass from which 18 PSCs were fabricated with a scalable and printable process; the resulting PSC after the mechanical infiltration of the precursor ink is shown in the right side. Architecture of (B) the over-sealed and (C) the side-sealed carbon-based PSCs. (D) Variation of the average normalized PCE of three replicates of over-sealed PSCs during thermal stability testing at 100 °C in the dark; each data point represents an average between the forward and reverse scans. Adapted and reprinted with permission from ref. 163 and 166.

only 4.5%. The sluggish degradation of the perovskite, with formation of PbI_2 , was observed and monitored by the camera imaging technique.

UV light exposure has been identified as one of the key issues for the evaluation of PSCs' long-term stability.^{168–171} For this reason, the same cells obtained by inkjet printing and stored without encapsulation were subjected to intense 1.5 sun UV light illumination in an electronic weather chamber, at 45% RH and 40 °C.¹⁶⁴ In the first 250 h, the cell ameliorated its performances in both J_{sc} (+17%) and PCE (8.6%); this behavior may be ascribed to the additional curing of perovskite crystals under UV light. After this time, a slow degradation of cell

performance started. Part of the dark-brown perovskite layer became yellow after 751 h, due to the formation of PbI_2 and the disappearance of HI and CH_3NH_2 . The J_{sc} reduced by 25% and the PCE by 28%. Some batches were sealed with epoxy glue to prevent contact with moisture. Epoxy did not dissolve any phase and did not penetrate into the carbon layer over the photo-active area. In these cells, the average J_{sc} and PCE were maintained after 1002 h. XRD demonstrated that PbI_2 reflections appeared only in epoxy-free aged samples. PL measurements demonstrated that the carrier lifetimes of batch 1 (without epoxy) and batch 2 (with epoxy) were 21.6 ns and 4.1 ns, respectively. This means that the epoxied samples were more likely to accelerate light-induced charge separation, thus restricting charge recombination, which correlated well with the results of aging tests.

Thermal stability is necessary for outdoor application of PSCs in many warm areas of the Earth, for example desert regions. However, the perovskite undergoes a phase transition from tetragonal to cubic at 54 °C.¹⁷² For these reasons, Baranwal *et al.* reported a three-layer printable HTM-free PSC with carbon as the back electrode, able to keep stability till 100 °C.¹⁶⁶ Despite the hydrophobic nature of this carbon component, owing to its porous nature, sealing of the device was necessary under high-temperature conditions. Sealing was conducted with a UV-cured gel and a glass cover, in two different configurations (over-sealed and side-sealed, as shown in Fig. 9B and C). Sealed and unsealed devices were kept at 100 °C before measuring J - V curves. Both the unsealed and over-sealed devices lost 20% of their initial efficiency in the first 30 h. In contrast, side-sealed devices did not degrade during thermal tests and their PCE remained constant over 1500 h (see Fig. 9D), suggesting that sealing is a necessary protection against moisture, but it could also cause internal decomposition in the over-sealed configuration.

Finally, the enlargement of the active area of the cell is a desirable goal for the real application of a PV solar cell. However, this task is not trivial when a thermal treatment, which may cause the cracking or the bending of the glass, is involved. Both high-temperature treated TiO_2 and carbon may suffer from poor uniformity and compactness. In 2018, De Rossi *et al.* reported the first example of A4-size carbon-based PSC, with an active area of 198 cm^2 .¹⁶⁷ They optimized the printing process with the method of edge registration to avoid short circuit and damage to the layers. The PSC was composed of 22 units, with dimensions of $5 \times 180 \text{ mm}^2$ and spaced by 6 mm, as shown in Fig. 10. A 1.5 mm-wide ZrO_2 layer and a low-temperature-treated TiO_2 layer were used as the insulator and blocking layer, respectively. A 10 μm -thick carbon layer was deposited by the doctor-blade technique in order to minimize the series resistance between adjacent units. With this large-area device, the highest PCE was 3.2%.

2.2 Low-temperature processed back electrodes

High-temperature thermal treatment of carbon-based electrodes is a time and energy-consuming method, that may limit large-scale manufacturing of PSCs.¹⁷³ In addition, high-temperature processed carbon cannot be applied in plastic and flexible devices.

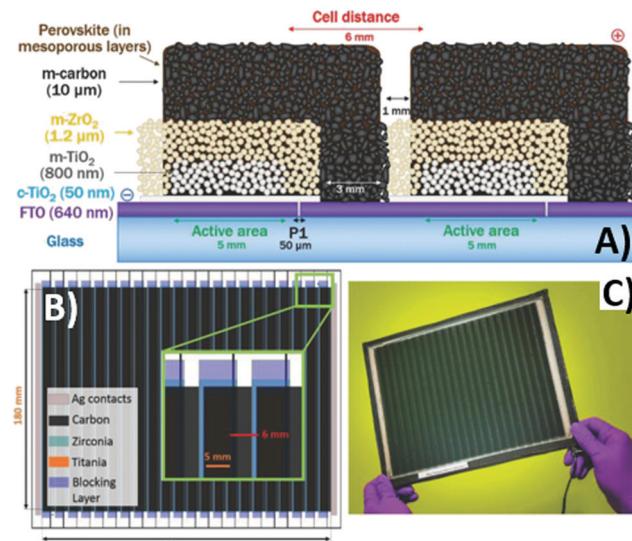


Fig. 10 (A) Cross-section schematics of adjacent cells in the module with nominal thickness of each layer, highlighting the laser-etched FTO, patterning of TiO_2 blocking layer and the electrical vertical connection, ensured by the carbon back contact; (B) module schematics, showing the different overlapping layers, the dimensions of the active area for both the individual single cell and the whole module as well as the distance between adjacent cells (inset); (C) photo of a module; wires have been soldered to the silver painted busbars to provide more robust electrical contacts. Adapted and reprinted with permission from ref. 167.

In 2014, Wei,¹⁷⁴ Zhou¹⁷⁵ and Zhang²² reported the first examples of low-temperature processed carbon electrodes for PSCs. In particular, the innovation introduced by Wei was the use of an ink containing both carbon and $\text{CH}_3\text{NH}_3\text{I}$ in isopropanol, that was directly printed on FTO/ TiO_2 / PbI_2 , as shown in Fig. 11A.¹⁷⁴ In this way, the deposition of the carbon layer and the formation of perovskite phase occurred simultaneously, ensuring an efficient interfacial contact between $\text{CH}_3\text{NH}_3\text{PbI}_3$ and carbon. For comparison, another cell was prepared by the “traditional” route: after the deposition of the carbon layer onto the FTO/ TiO_2 / PbI_2 substrate, the cell was soaked into the $\text{CH}_3\text{NH}_3\text{I}$ solution. The intimate contact between the two phases was better in the first case, when carbon was deposited together with the $\text{CH}_3\text{NH}_3\text{I}$ solution, as confirmed in the SEM images shown in Fig. 11B and C. Recombination resistance (R_{rec}) was estimated by fitting EIS data. It was confirmed that charge recombination was several times lower in the cell obtained with the $\text{CH}_3\text{NH}_3\text{I}$ /carbon ink. Consequently, PV parameters improved: V_{oc} increased from 0.90 to 0.95 V, J_{sc} from 15.00 to 17.20 mA cm^{-2} , FF from 0.63 to 0.71 and PCE from 8.51 to 11.60%. Finally, devices maintained about 90% of their initial PCE after 12 days of dark storage without sealing.

Zhou *et al.* investigated for the first time the influence of carbon layer thickness on the performance of low-temperature processed PSCs.¹⁷⁵ Carbon particles were dispersed in chlorobenzene and deposited by the doctor-blade technique, varying the thickness in the range 2–40 μm . It was found that the PCE of devices increased with carbon layer thickness till a maximum of 20 μm . 2.1 μm -thick carbon presented a high sheet resistance



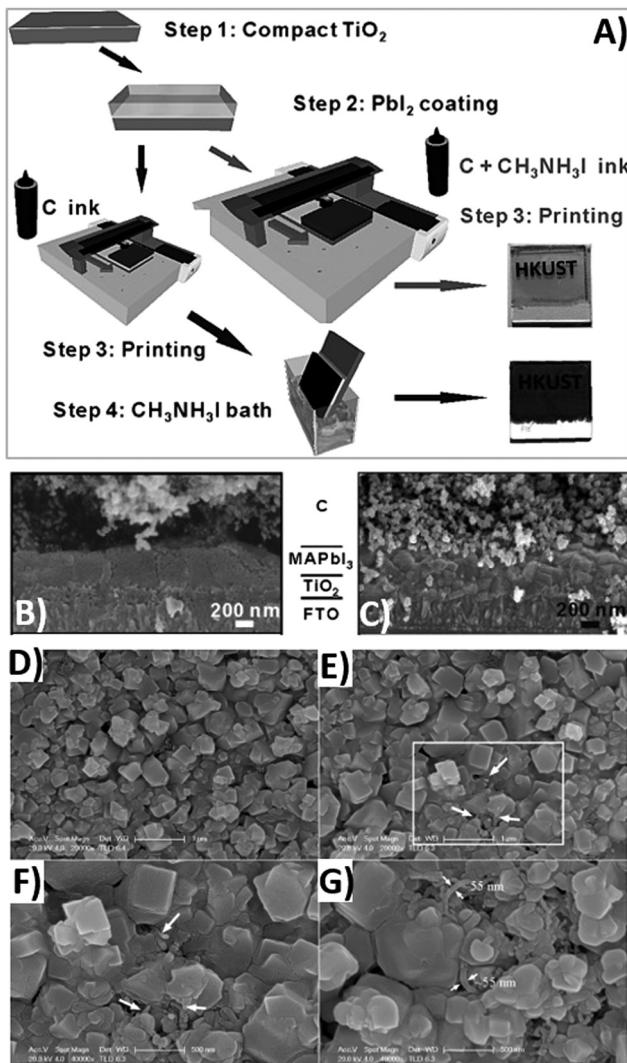


Fig. 11 (A) Fabrication process flow for the instant inkjet printing of the carbon/CH₃NH₃PbI₃ planar PSCs; cross-sectional SEM images of TiO₂/CH₃NH₃PbI₃/carbon solar cells prepared by the inkjet printing technique using (B) a carbon ink and (C) a carbon + CH₃NH₃I ink (the increased interconnectivity between the perovskite and carbon phase can be clearly seen in the right image). (D) Planar SEM images of a pristine perovskite film and of (E–G) films obtained with addition of 0.1 mg mL^{−1} MWCNTs: the contact between perovskite grains was increased after the addition of MWCNTs. Adapted and reprinted with permission from ref. 174 and 179.

of 160 Ω, therefore the corresponding cell exhibited a poor PCE of 2.25%. On the other hand, the best PCE of 6.90% was obtained with a carbon layer thickness of 20.6 μm. Even though a clear explanation for this structure–performance correlation was not provided by the authors, cell stability was confirmed for up to 2446 h. Such a good result under long-term testing was ascribed to the presence of hydrophobic carbon, which impeded the penetration of moisture, and to the absence of noble metals, which could corrode CH₃NH₃PbI₃.

The intrinsic resistivity of graphite is high. However, it can be reduced by introducing carbon black NPs (CBNPs)¹⁷⁶ and nano-graphite powder¹⁷⁷ or by ameliorating carbon morphology.¹⁷⁸ Within the carbon electrode, charge transportation is provided

mainly by graphite flakes; the addition of CBNPs facilitates the connections between them and improves the interfacial contact with the perovskite phase.¹⁷⁶ In literature studies, PV parameters were influenced by the relative content of CBNPs with respect to graphite. In fact, the addition of CBNPs in the ratios 5:1 and 3:1 dramatically increased the PCE, as shown in Table 4 (entries I–III). This improvement was attributed to the reduced sheet resistance of the carbon material, that changed from 1.11 to 0.69 Ω cm (after having been pressed at 0.25 MPa). However, a further increase of CBNPs (ratio 2:1) slightly diminished cell performances (see Table 4, entry IV); in fact, an excess of CBNPs brought about a stronger recombination.¹⁷⁶

A similar strategy was followed by Liu and coworkers.¹⁷⁷ Besides CBNPs, they also explored the effect of nano-graphite powder with different particle dimensions of 40 and 400 nm. The introduction of nano-graphite powder made the carbon film more compact and improved the interfacial contact. Thus, PV performances ameliorated after the introduction of nano-graphite powder. Table 4 (entries VI and VII) reveals that cells containing smaller nano-graphite powder (40 nm) perform better than cells containing larger graphite powder (400 nm). Larger particles decreased the contact between grains, establishing an overpotential at the interphase. However, increasing the content of 40 nm-graphite powder did not lead to a further increase of PCE (see Table 4, entry VIII). In fact, too much nano-graphite powder could have led to higher resistance and stronger recombination.

It has to be noted that, even though the cell architectures are identical, PCE values obtained by Wei¹⁷⁶ are remarkably higher than those obtained by Liu¹⁷⁷ (13.53% vs. 4.47%, respectively), as shown in Table 4 (entries III and V). In fact, the latter researcher fabricated the devices under uncontrolled high humidity conditions, which may have deteriorated the perovskite layer, thus limiting the PCE.

The poor interface contact between carbon and the perovskite phase is the main efficiency-limiting factor of low-temperature carbon-based PSCs with respect to gold-based PSCs. In fact, commercial carbon pastes contain solvents that, during evaporation, can create bulges and pinholes in the material, and also the perovskite layer may present holes that are not filled with the carbon material. A suitable solution to overcome this issue was proposed by Zhang *et al.* in 2018.¹⁷⁸ They fabricated a self-adhesive carbon film, processed at room temperature by the solvent exchange method. A carbon electrode, namely C2, was doctor-bladed on a glass, soaked in ethanol and dried. It exhibited a macroporous, flexible morphology, with a thickness of 60 μm. It was removed from the glass and pressed onto the perovskite layer. The adhesion was ensured by its compressibility: in fact, the thickness was reduced to 31.9 μm, allowing an optimal contact at the interphase. Furthermore, after being pressed, its sheet resistance decreased from 424 to 58 Ω sq^{−1}. For comparison, a carbon electrode, namely, C1, with a similar thickness was created by the traditional route at 100 °C, without being soaked in ethanol and transferred from another substrate. As expected, the PCE of the C2-cell was dramatically higher than that reached by the C1-based cell (19.2% vs. 15.2%, see Table 4, entry IX).

Table 4 Comparison between PV parameters, obtained under 1 sun illumination, for PSCs fabricated by varying the composition of the carbon-based electrode

Entry	Carbon electrode composition	V_{oc} (V)	J_{sc} (mA cm $^{-2}$)	FF	PCE (%)	Ref.
I	Graphite	0.97	18.8	0.57	10.27	176
II	Graphite/CBNPs 5:1	0.98	20.0	0.58	11.43	176
III	Graphite/CBNPs 3:1	1.00	21.3	0.63	13.53	176
IV	Graphite/CBNPs 2:1	0.97	20.6	0.62	12.47	176
V ^a	Graphite/CBNPs 3:1	0.79	13.0	0.43	4.47	177
VI ^a	Graphite/CBNPs/nanographite powder (400 nm) 1:1:2	0.82	14.9	0.43	5.31	177
VII ^a	Graphite/CBNPs/nanographite powder (40 nm) 1:1:2	0.84	16.8	0.43	6.16	177
VIII ^a	Graphite/CBNPs/nanographite powder (40 nm) 1:1:5	0.87	11.0	0.40	3.84	177
IX	Self-adhesive carbon film	1.08	23.3	0.76	19.2	178
X	Carbon	0.87	20.2	0.56	9.8	179
XI	Carbon/MWCNT	0.93	21.3	0.59	11.6	179

^a Indicates cells fabricated under high humidity conditions.

Another suitable solution to overcome the poor contact between the perovskite phase and carbon back electrode was proposed by Cheng *et al.* in 2016.¹⁷⁹ As demonstrated by the SEM image shown in Fig. 11D, the $\text{CH}_3\text{NH}_3\text{PbI}_3$ layer had a rough surface, with particles of different dimensions. On the other hand, the carbon material was composed of nano-sized carbon black and micro-sized graphite flakes. The latter, due to the large dimension, did not provide an effective contact with perovskite crystals, thus reducing the PCE to 9.8% (see Table 4, entry X). To solve this issue, MWCNTs were used. CNTs consist of a graphene layer bent and joined in one direction, to form a hollow cylinder. MWCNTs are composed of more nested CNTs, aligned together. Similar to other graphene-based materials, CNTs exhibit high electrical conductivity and thermal stability.¹⁸⁰ MWCNTs with a diameter of 55 nm were added in the perovskite phase in order to fill the gap between larger and smaller particles, thus creating the interconnect network shown in Fig. 11E–G, where photogenerated charges can easily be transferred. In the MWCNT-based devices, an average PCE of 11.6% was achieved (see Table 4, entry XI).

Zhang²² and Liu¹⁸¹ studied the effect of the nature of the TiO_2 anode in low-temperature carbon PSCs. In particular, Zhang²² focused on the effect of TiO_2 thickness that ranged from 190 to 830 nm by varying the precursor concentration. A too thin TiO_2 film (190 nm) cannot support enough quantity of perovskite, making the electron extraction ineffective. This cell provided a low PCE of 2% and a very low V_{oc} of 0.70 V. On the other hand, a too thick TiO_2 film increased the probability of electron recombination. The optimal thickness was 630 nm, which provided the best performing devices, with a V_{oc} of 0.82 V, a J_{sc} of 16.10 mA cm $^{-2}$, FF of 52.60 and PCE of 7.40%.

The aim of Liu's work was instead the study of the effect of the TiO_2 blocking layer between FTO and TiO_2 anode.¹⁸¹ An efficient blocking layer favors the extraction of photogenerated electrons and impedes charge recombination and should not present voids or cracks, which may act as recombination centers. However, during the synthesis of TiO_2 by the sol–gel process, the widely used precursor $\text{Ti}(\text{OC}_4\text{H}_9)_4$ undergoes hydrolysis under atmospheric conditions, resulting in a non-uniform morphology of TiO_2 . For these reasons, different amounts of diethanolamine (DEA), whose basic character hampers the

hydrolysis of $\text{Ti}(\text{OC}_4\text{H}_9)_4$, were added in the precursor solution. SEM images confirmed that the DEA-free TiO_2 blocking layer presented many cracks and voids, with a width of ≈ 400 nm, that can act as recombination centers. On the other hand, DEA-containing films were compact and homogeneous and fully covered the FTO substrate. A remarkable PCE of 11.92% was observed when a $\text{Ti}(\text{OC}_4\text{H}_9)_4$:DEA = 1:0.75 ratio was used.

Besides carbon, TiO_2 and insulating ZrO_2 also require high-temperature sintering and are not suitable for flexible applications, thus hindering the fabrication of PSCs. ZnO is a suitable n-type semiconductor, which requires only low-temperature processing (120 °C) and can be deposited by spin coating.¹⁸² Since its conduction band is at a lower energy with respect to that of the perovskite, electron injection is possible between excited $\text{CH}_3\text{NH}_3\text{PbI}_3$ and ZnO , as shown in Fig. 12A. Therefore, it can replace the role of TiO_2 . In 2015, Zhou *et al.* reported the first example of a TiO_2 - and HTM-free carbon-based PSC with the simple architecture $\text{ZnO}/\text{CH}_3\text{NH}_3\text{PbI}_3/\text{carbon}$.¹⁸² The thickness

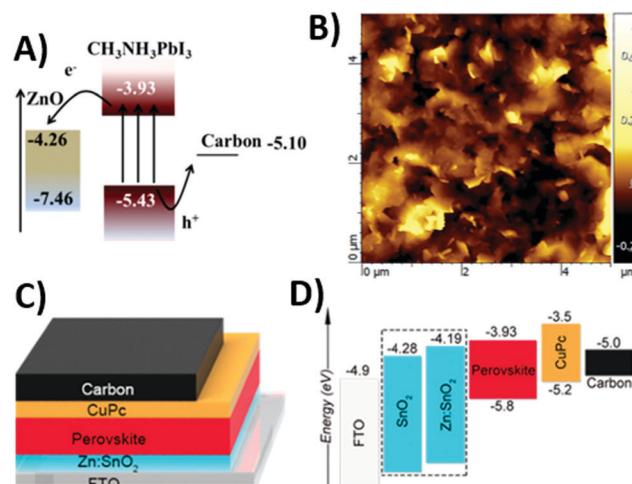


Fig. 12 (A) Band alignment in $\text{ZnO}/\text{CH}_3\text{NH}_3\text{PbI}_3/\text{carbon}$, underlying electron and hole injection from the perovskite and ZnO and carbon, respectively. (B) AFM image of the graphite film on a glass/ITO/ $\text{ZnO}/\text{CH}_3\text{NH}_3\text{PbI}_3$ substrate (ITO = indium-doped tin oxide). (C) Schematic cell architecture and (D) energy level diagram for a FTO/ Zn:SnO_2 /perovskite/CuPc/carbon device. Adapted and reprinted with permission from ref. 182, 183 and 186.



of the ZnO layer had a strong influence on PSC efficiency. In fact, a too thin layer (25 nm) was not completely covered by the active material and presented many holes. Its PCE and V_{oc} were limited to 0.90% and 0.47 V, respectively. On the other hand, a too thick ZnO layer (89 nm) showed a high series resistance and an increased recombination rate. In fact, PCE reached a small value of 3.55%, even though its V_{oc} of 0.80 V was the highest found in this kind of system. The optimal ZnO thickness was found to be 55 nm (V_{oc} of 0.74 V, J_{sc} of 20.68 mA cm⁻², FF of 0.46 and PCE of 7.05% in the forward scan).

Another ZnO-based low-temperature processed PSC was reported by Jin *et al.* in 2015.¹⁸³ In this work, all films were deposited at room temperature. An electrochemically exfoliated graphite layer was used as the HTM to improve the extraction efficiency between the perovskite and the carbon back electrode. The obtained graphene had an excellent hole mobility of ≈ 310 cm² V⁻¹ s⁻¹. The atomic force microscopy (AFM) image (Fig. 12B) showed that the thickness of graphene sheets was lower than 10 nm, corresponding to 30 atomic layers and the majority of graphite was in the form of NPs. Overall, the carbon-based back electrode was quite compact and completely covered the perovskite film. An average PCE of 7.2% was reached with this architecture.

SnO₂ is a high band-gap semiconductor ($E_g = 3.6$ eV), with high charge mobility and without a UV photocatalytic effect.¹⁸⁴ It has already been employed to replace mesoporous TiO₂ as the anode material for PSCs, due to its low-temperature processability.¹⁸⁵ Metal doping of SnO₂ further increases its electronic properties, making it more suitable for application in the PSC field. In particular zinc-doping shifts the work function of SnO₂ from -4.28 to -4.19 eV, resulting in a more favorable band alignment, as shown in Fig. 12C. Ye *et al.* reported in 2019 an entirely low-temperature processed carbon-based PSC with a Zn-SnO₂ ETM, as shown in Fig. 12D.¹⁸⁶ FF and PCE were strongly improved, with respect to the undoped SnO₂-based cell. In particular, PCE increased from 15.31% to 17.78%. The more favorable band alignment generated a stronger electron injection from the excited active material to the ETM.

Even if not necessary, the HTM plays the important role of helping in hole extraction and ameliorating surface contact between the perovskite phase and carbon electrode. The most common organic HTM in gold-based PSCs is spiro-OMeTAD, which is expensive and needs to be doped with LiTFSI to improve conductivity. The latter is a hygroscopic salt that threatens the stability of the perovskite layer.¹⁸⁷ Many efforts have been made for the replacement of spiro-OMeTAD with polymeric,^{188,189} organic^{24,190,191} and inorganic HTMs.¹⁹²⁻¹⁹⁴ In this framework, poly(3-hexylthiophene) (P3HT) is an intrinsic semiconductor with high stability (up to 350 °C in air) and low cost. Mashhoun *et al.* showed in 2018 that it can efficiently work as the HTM in carbon-based PSCs.¹⁸⁸ Since the carbon back electrode is usually deposited from carbon pastes, the solvent content in the suspension should not be harmful for the underlying layer. For this reason, the effect of the nature of the solvent was investigated. In particular, the lowest and the highest PCEs were found with chlorobenzene and toluene,

Table 5 PV performances of P3HT-based PSCs with various solvents used for the preparation of the carbon ink, as proposed by Mashhoun *et al.*¹⁸⁸

Entry	Solvent	P3HT solubility (mg mL ⁻¹)	V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF	PCE (%)
I	Chlorobenzene	15.9	0.545	6.27	0.36	1.27
II	Xylene	2.7	0.662	13.46	0.40	3.45
III	Toluene	0.7	0.764	15.86	0.42	5.04
IV	Toluene ^a	0.7	1.012	16.35	0.70	11.58

^a Indicates a cell with TaWO_x-doped P3HT.

respectively (see Table 5, entries I-III). PV performances ameliorated by decreasing the solubility of P3HT in the solvent, but a clear explanation was not given by the authors. Further interface engineering with TaWO_x NPs ameliorated the contact between P3HT and carbon, thus enhancing the PCE from 5.04% to 11.58%, as shown in Table 5 (entry IV).

The charge extraction and transport ability of P3HT can be further increased by the addition of graphene. In fact, graphene is a 2D dimensional graphite layer, with high electrical conductivity and thermal stability. In 2019, Chu *et al.* reported the use of a P3HT/graphene composite as an efficient HTM for carbon-based PSCs.¹⁸⁹ The improved properties of the composite were demonstrated by the increase of both PCE and J_{sc} . PCE shifted from 11.1% to 17.5% and J_{sc} from 19.3 to 22.3 mA cm⁻². FF increased by 45% (from 0.51 to 0.74), suggesting the better contact between the perovskite and the HTM. In their work, a record PCE of 18.2% was reported in the reverse scan.

Small molecule-based HTMs have the advantages of facile synthesis and tunable electronic properties. In addition, in most cases, they do not require the use of a dopant to increase conductivity. Among organic HTMs, copper phtalocyanine (CuPc) is noteworthy.¹⁹⁵ It is a strong conjugated planar molecule, with a tendency to form π - π stacking in the film state. Its p-type semiconductor character, low cost, ease of preparation, good thermal stability and long charge diffusion length make it the ideal candidate as the HTM in PSCs.¹⁹⁶⁻¹⁹⁸ Zhang *et al.* used for the first time CuPc as the HTM in carbon-based PSCs.¹⁹⁰ Results underlined the importance of CuPc, since every PV parameter improved with respect to the HTM-free cell. In particular, the PCE increased from 9.0 to 16.1%. For comparison, an analogous cell with spiro-OMeTAD as the HTM was also reported. It showed an efficiency of 15.0%, that was still lower than that of the CuPc-cell. In addition, the device with CuPc was more stable: PCE dropped by only 8.5% in 600 h, as shown in Fig. 13A.

Another π -delocalized small molecular HTM was reported by Zhang *et al.* in 2015.²⁴ Triazatruxene (TAT) contains three indole units combined by one benzene. Due to its electron rich aromatic structure, it has a strong charge carrier ability and has already been employed as the HTM in the field of organic PVs.^{199,200} Its derivative 5,10,15-triphenyl-5H-diindolo[3,2-a:3',2'c]-carbazole (TPDI) shows the same properties and, in addition, exhibits good thermal stability and compatible band alignment with both carbon and CH₃NH₃PbI₃. When both TPDI and spiro-OMeTAD were doped with LiTFSI, TPDI-based cells showed comparable PCE with respect to spiro-OMeTAD-based ones



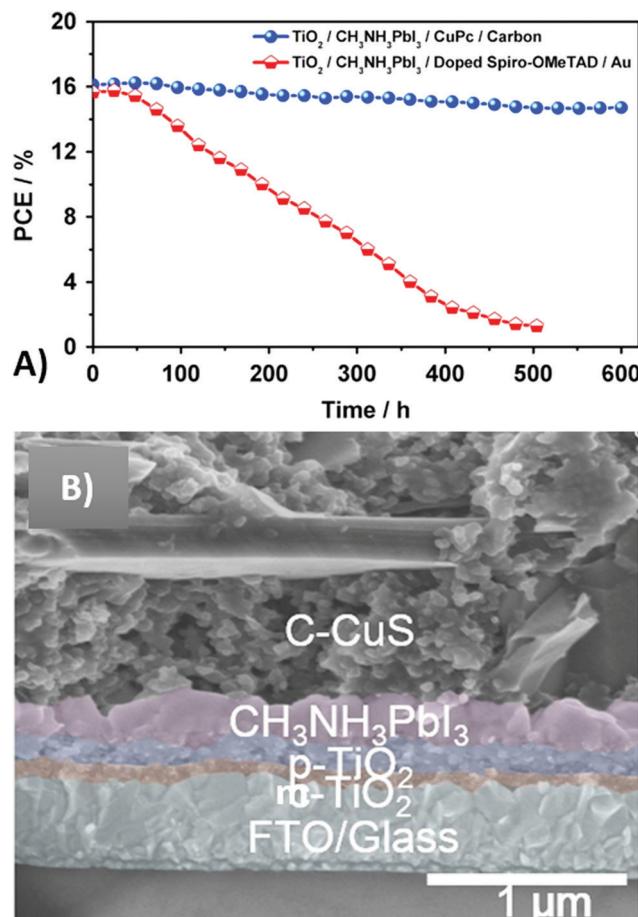


Fig. 13 (A) Stability tests of PSCs with CuPc/carbon and doped-spiro-OMeTAD/gold as the HTM and back electrode, respectively. (B) Cross-sectional SEM image of a glass/FTO/c-TiO₂/m-TiO₂/CH₃NH₃PbI₃/Carbon-CuS device, with the following thicknesses: c-TiO₂ (70 nm), m-TiO₂ (170 nm), perovskite layer (340 nm), carbon electrode (10 μm). Adapted and reprinted with permission from ref. 190 and 192.

(15.5% *vs.* 15.1%, respectively), but without the disadvantages of spiro-OMeTAD. However, the difference was more prominent when the pristine materials were used as the HTM: 13.6% *vs.* 10.8%, respectively. This inferior performance was ascribed to the relative pure charge transportation ability of spiro-OMeTAD in the absence of a p-dopant and to a larger series resistance. Devices assembled with undoped-TPDI exhibited an increased stability due to its strong hydrophobicity, which prevented the contact between the perovskite and air-moisture. In this kind of cell, the optimal carbon thickness was 10 μm; in fact, 5 μm-thick carbon provided very poor conductivity, while 20–30 μm-thick carbon increased the conductivity, but did not pump PCE. The optimal carbon thickness was different from that reported by Zhou (20 μm), underlining that in the presence of this specific HTM a thinner graphite layer was required.¹⁷⁵

In the class of small molecule-based organic HTMs, fluorinated compounds show interesting properties, even though they have not been fully investigated. Due to the small dimension and strong electronegativity of fluorine, fluorination is a suitable strategy for decreasing the energy level, ameliorating hole-extraction at

the HTM/perovskite interface.¹⁹¹ A novel fluorinated HTM was reported by Ren *et al.*, *i.e.* BDT2MeDPA, composed of difluorobenzene, benzo[1,2-*b*:4,5-*b*']dithiophene (BDT) and 4,4'-dimethoxydiphenylamine (DPA) groups.¹⁹¹ Electro-donating BDT presented excellent charge transport properties and facilitated the synthetic process. For comparison, the fluorine-free counterpart (BDT0MeDPA) was also used as the HTM. PV performance remarkably increased with the use of the novel HTM. When BDT0MeDPA was used, J_{sc} shifted from 12.5 to 17.2 mA cm⁻² and the PCE increased from 8.4% to 11.3%, while V_{oc} maintained a constant value of 0.98 V. BDT2MeDPA-based cells showed a further increase in J_{sc} (21.4 mA cm⁻²) and PCE (14.5%), that were slightly lower than those obtained with spiro-OMeTAD (PCE = 15.2%). PL quenching was stronger in the BDT2MeDPA/perovskite than in the BDT0MeDPA/perovskite, underlining the well matched energy levels and efficient charge extraction process.

Inorganic p-type HTMs are more thermally stable with respect to molecular ones.²⁰¹ The most commonly used are CuS,¹⁹² CuSCN¹⁹³ and NiO.¹⁹⁴ CuS has already been investigated in DSSCs,²⁰² and was reported as the HTM for PSCs for the first time in 2018. Hu *et al.* fabricated a carbon-based PSC where small particles of CuS, obtained by a low-temperature precipitation process, were added to the carbon paste to increase the hole-extraction ability of the cathodic hybrid material.¹⁹² The resulting carbon electrode had a thickness of 10 μm and CuS presented its nanostructure form below 100 nm, as shown by SEM image in Fig. 13B. The EDX spectrum evidenced the homogeneous distribution of CuS into the carbon electrode.

CuS was added in the carbon paste in the ratio of 0.5–2 wt%. $J-V$ curves evidenced that a small CuS-doping increased by 21% the performances of the carbon-based PSCs. The average PCE shifted from 8.41% for the undoped device to 9.32% for the 0.5%-doped one and 10.22% for the 1%-doped one, highlighting the increased hole collection ability of the doped electrode. On the other hand, efficiency reduced when the amount of CuS exceeded 1 wt%, due to the smaller conductivity of CuS with respect to graphite. For these reasons, the optimal amount of CuS was 1 wt%.

Another copper-based inorganic HTM was reported by Lv *et al.* in 2018.¹⁹³ CuSCN is an inorganic p-type semiconductor, with low cost and high stability. It was deposited by spin coating under the perovskite layer with a thickness of 300 nm and established a good contact with both the absorber material and carbon back electrode. It caused a strong emission quenching in the PL spectrum of the perovskite, highlighting its effective contact and suitable band alignment with CH₃NH₃PbI₃. The effect of CuSCN on the PV performance was remarkable: V_{oc} shifted from 0.72 to 0.78 V, J_{sc} from 17.32 to 19.58 mA cm⁻², FF from 0.53 to 0.59 and PCE from 6.61% to 9.01%. This result was confirmed by Mashhoun,¹⁸⁸ who found a PCE of 8.59% for CuSCN-based devices.

As already said, NiO has been largely used as the HTM in high-temperature processed carbon-based PSCs.^{150–152} Its properties of hole conduction and electron blocking effect have been exploited to suppress recombination and increase both V_{oc} and J_{sc} .



However, in high-temperature processed PSCs the poor pore filling causes an inhomogeneous crystallization of the perovskite and this issue is worsened when NiO is used as the HTM. In 2017, Peiris *et al.* reported for the first time a mesoscopic PSC, with NiO as the HTM and low-temperature processed carbon as the back electrode.¹⁹⁴ The perovskite was deposited on the FTO/TiO₂/ZrO₂/NiO substrate by a modified one-step method in the presence of N₂ flow. Subsequently, the carbon film was doctor-bladed on top of NiO: this strategy solved the problem of poor crystallization of CH₃NH₃PbI₃. The PCE was almost doubled up from 5.96% to 10.35% by the presence of NiO. A lower charge transfer resistance was measured by EIS in the NiO-based device, confirming the more effective charge extraction and transfer. In addition, recombination resistance was stronger in NiO-based cells, suggesting that charge recombination was lower.

Another suitable strategy for replacing time and energy-consuming sintering is the NIR technology, that has already been used to thermally treat TiO₂ for DSSC application.²⁰³ NIR wavelengths are absorbed by a substrate, and converted into heat, causing the rapid warming of the substrate.²⁰⁴ If the substrate is transparent in the NIR range, a metal can be exploited to transfer heat. This method is very fast and allows energy saving. In 2017, Baker *et al.* reported the use of NIR technology for rapid thermal treatment (12.5 s) in mesoporous carbon-based PSCs.²⁰⁵ Both TiO₂

and ZrO₂ are transparent in the NIR range, so, when they were deposited and treated with NIR, radiation reached the FTO. The heat generated was enough to burn out all the organic additives of the two pastes. On the other hand, carbon has a high absorption coefficient in the NIR range; so, it absorbed all the radiation that, in this way, did not reach the underlying layer. Heat was generated only in the carbon layer, allowing the evaporation of solvents and volatilization of organic compounds present within the carbon paste. Consequently, the as-formed mesoporous layer was successfully infiltrated with the perovskite precursor solution. To the best of our knowledge, this is the only example of mesoscopic carbon-based PSCs obtained without thermal treatment. The champion device reached a J_{sc} of 20 mA cm⁻² and a stabilized PCE of 11%.

As concluding remarks, a comparison of sheet resistance and thickness of carbon-based back electrodes prepared following different recipes, along with the best PCE values of the resulting devices, is given in Table 6 (for carbon-infiltrated perovskites) and Table 7 (for layered carbon electrodes).

Within the comparison between high and low temperature processes for the fabrication of carbon-based PSCs, it should be stressed that this distinction just refers to the preparation of cell components and device assembly. Indeed, many carbon electrode recipes contain graphite flakes that quite always come from synthetic sources, the latter requiring very high temperature treatments. Therefore, a life cycle assessment (LCA) study of

Table 6 Comparison of sheet resistance and thickness of carbon-based back electrodes prepared following different recipes; the best PCE values of the resulting devices are also listed. The table refers to carbon-infiltrated perovskites

Paste composition	Deposition technique	Thermal treatment	Sheet resistance (Ω cm ⁻²)	Thickness (μm)	PCE (%)	Ref.
CB/flaky graphite	Blade coating	400 °C for 30 min	10.49	10	4.08	29
CB/spheroidal graphite	Blade coating	400 °C for 30 min	8.02	10	6.64	29
2 g CB (particle size 30 nm), 6 g graphite powder, 1 g ZrO ₂ (particle size 20 nm), 1 g hydroxypropyl cellulose in 30 mL terpineol	Blade coating	400 °C for 30 min	11.47	9	11.63	87
9 g graphite powder (particle dimension <20 μm), 3 g CB, 1 g ZrO ₂ (particle dimension <100 nm), 15 g ethylcellulose in 18 g terpineol	Screen-printing	400 °C for 30 min	56	25	10.7	88
5 g graphite, 1 g CB (particle size 30 nm), 1 g ZrO ₂ (particle size 20 nm), terpineol (30 mL)	Blade coating	400 °C for 30 min	Not reported	Not reported	13.7	151
BG, CB, hydroxypropyl cellulose, terpineol	Printing	400 °C for 30 min	5–20	5–16	12.63	94
UG (obtained by exfoliation of BG), CB, hydroxypropyl cellulose, terpineol	Printing	400 °C for 30 min	5–25	5–16	14.01	94
Carbon material (graphite:CB = 3:7), hydroxypropyl cellulose, terpineol	Screen-printing	400 °C for 30 min	23	11	15.70	92
4 g graphite, 1 g CB, 0.6 g ZrO ₂ , in ethanol	Screen-printing	400 °C for 60 min	30.5	Not reported	3.36	95
3.8 g graphite, 0.95 g CB, 0.57 g ZrO ₂ , 0.28 g polystyrene spheres in ethanol	Screen-printing	400 °C for 60 min	56.7	Not reported	3.87	95
3.6 g graphite, 0.9 g CB, 0.54 g ZrO ₂ , 0.56 g polystyrene spheres in ethanol	Screen-printing	400 °C for 60 min	68.3	Not reported	4.10	95
2.8 g graphite, 0.7 g CB, 0.42 g ZrO ₂ , 1.68 g polystyrene spheres in ethanol	Screen-printing	400 °C for 60 min	180.7	Not reported	3.13	95
6.5 g graphite, 2 g CB, 1 g ZrO ₂ , 1 g hydroxypropyl cellulose, 30 mL terpineol	Screen-printing	400 °C for 30 min	35	11	12.4	157
6.5 g BdG, 2 g CB, 1 g ZrO ₂ , 1 g hydroxypropyl cellulose, 30 mL terpineol	Screen-printing	400 °C for 30 min	16	9.6	13.6	157
CB (5 wt%), Al ₂ O ₃ (5 wt%), graphite (10 wt%), ethyl cellulose (20 wt%), terpineol (60 wt%)	Screen-printing	125 °C for 10 min, 325 °C for 10 min, 375 °C for 10 min, 400 °C for 30 min	Not reported	4–5	12.12	152
2 g CB (particle size 30 nm), 6.5 g graphite, 1 g ZrO ₂ (particle size 20 nm), 1 g hydroxypropyl cellulose, 30 mL terpineol	Screen-printing	400 °C for 30 min	8.98	10	14.15	153



Table 7 Comparison of sheet resistance and thickness of carbon-based back electrodes prepared following different recipes; the best PCE values of the resulting devices are also listed. The table refers to layered carbon electrodes

Paste composition	Deposition technique	Thermal treatment	Sheet resistance ($\Omega \text{ cm}^{-2}$)	Thickness (μm)	PCE (%)	Ref.
15 mg mL ⁻¹ CB in 2-propanol	Screen-printing	100 °C for 60 min	Not reported	Not reported	7.55	174
15 mg mL ⁻¹ CB, 10 mg mL ⁻¹ $\text{CH}_3\text{NH}_3\text{I}$ in 2-propanol	Screen-printing	100 °C for 60 min	Not reported	Not reported	10.03	174
20 wt% polyvinyl acetate, 80 wt% carbon material (graphite:CB = 1:0)	Doctor blade	85 °C for 15 s	1.11	40	10.27	176
20 wt% polyvinyl acetate, 80 wt% carbon material (graphite:CB = 5:1)	Doctor blade	85 °C for 15 s	0.75	40	11.43	176
20 wt% polyvinyl acetate, 80 wt% carbon material (graphite:CB = 3:1)	Doctor blade	85 °C for 15 s	0.69	40	13.53	176
20 wt% polyvinyl acetate, 80 wt% carbon material (graphite:CB = 2:1)	Doctor blade	85 °C for 15 s	0.61	40	12.47	176
Commercial carbon paste (CC, Shenzhen DongDaLai Chemical Co., Ltd)	Doctor blade	100 °C for 30 min	6.4	10	16.1	190
Graphite flakes (10 μm):CB (40 nm) = 3:1 in ethyl acetate	Doctor blade	Not reported	17	65	4.47	177
Graphite flakes (10 μm):CB (40 nm):nano-graphite powder (400 nm) = 1:1:2 in ethyl acetate	Doctor blade	Not reported	70	65	5.31	177
Graphite flakes (10 μm):CB (40 nm):nano-graphite powder (400 nm) = 1:1:2 in ethyl acetate	Doctor blade	Not reported	100	65	6.16	177
Graphite flakes (10 μm):CB (40 nm):nano-graphite powder (400 nm) = 1:1:2 in ethyl acetate	Doctor blade	Not reported	170	65	3.84	177
Graphite, CB, PMMA (binder), Y-037 (solvent)	Doctor blade	100 °C for 20 min	Not reported	10	10.22	192
Commercial carbon paste (Guangzhou Saidi Technology Co., Ltd)	Doctor blade	100 °C (until the residual solvent is totally evaporated)	10.9	34.5	15.2	178
Commercial carbon paste (Guangzhou Saidi Technology Co., Ltd). The layer was soaked in ethanol to remove the residual solvent	Doctor blade	100 °C	58.6	31.9	19.2	178
Commercial carbon paste (Shenzhen DongDaLai Chemical Co., Ltd)	Printing	Not reported	Not reported	Not reported	17.78	186
Commercial carbon ink (Jujo printing supplies & technology (pinghu) co., Ltd)	Blade coating	100 °C for 15 min	Not reported	11.2	11.92	206

carbon-based PSCs (out of the scope of this review) should also consider the preparation of the graphite part of the electrodes, independently if the device assembly contains a high temperature step or not. A LCA study of a pre-industrial production process of large-area perovskite modules based on a carbon stack architecture was recently proposed by Alberola-Borràs *et al.*²⁰⁷ The perovskite layer was found to be the one with the greatest impact, mainly due to the energy consumed in the preparation and annealing of the precursor solution, rather than the lead content. As regards the back electrode, the inventory of the photovoltaic module included input/output relative to carbon, nitrocellulose, terpineol, screen-printing, annealing at 400 °C for 30 min, emissions and transportation burden by a lorry. No relevant mention was present concerning the source of carbon, therefore we further highlight the necessity to consider this point in future LCA approaches. Of course, if the carbon source comes from biomass or biosourced matter, the outcome of the LCA analysis will be markedly affected.

3 Graphene-based back electrodes

Among carbon-based materials, graphene, a 2D dimensional sheet of sp^2 carbon atoms packed into a honeycomb crystal lattice, is surely noteworthy. Graphene presents several remarkable properties, such as high surface area, high charge mobility, both electrical and thermal conductivity, large mechanical flexibility and transmittance (it absorbs only 2.3% of the incident

radiation from infrared, IR, to visible range).²⁰⁸ Due to its unique characteristics, it has been reported for catalysis,²⁰⁹ sensors²¹⁰ and optoelectronic devices (diodes, displays, solar cells, *etc.*).^{211,212} Concerning PSCs, many reviews summarize the applications of graphene.^{208,213–216} In particular, its high flexibility and transmittance make it suitable for numerous applications in flexible, portable and inverted PSCs.^{161,217,218} Both planar and mesoscopic normal architectures require the use of high-temperature processed TiO_2 to form a compact film. This issue is not only time- and energy-consuming, but also impedes the fabrication of plastic and flexible devices. On the other hand, in inverted architectures, the device is illuminated from the back electrode side. Photogenerated electrons and holes are collected by the ETM and HTM and reach the aluminum anode and the carbon electrode, respectively. Consequently, the latter needs to be highly transparent in both the visible and IR range. For this reason, graphene is the ideal candidate.²⁰⁸ Finally, the use of a transparent conductive oxide (TCO) is not necessary; indeed, plastic and transparent materials can be used, allowing the fabrication of flexible devices.

The first example of the use of graphene as the transparent electrode in inverted PSCs was reported by You *et al.* in 2015.¹⁶¹ Graphene was synthesized by the CVD method on copper foils, then coated with poly(methyl methacrylate) (PMMA) and poly(dimethylsiloxane) (PDMS). The resulting graphene/PMMA/PDMS sample was peeled off from the substrate and deposited onto a perovskite/HTM layer. Poly(3,4-ethylenedioxythiophene)-poly(styrenesulfonate) (PEDOT:PSS) was used to increase the



hole extraction ability of graphene and ameliorate the contact with the perovskite. Furthermore, the addition of d-sorbitol to PEDOT:PSS improved the contact of the graphene layer with the HTM and the perovskite, and increased the PCE from 4.13% to 12.37% when the devices were illuminated from the FTO side. However, the PCE was almost the same when the graphene side was illuminated: 4.37% and 12.02% for devices without and with d-sorbitol, respectively. The PCE was strictly dependent on the number of graphene layers. The device with two layers showed the best PV parameters, with an efficiency of 12.37% vs. 9.18% for the cell assembled with the single layer. However, further increasing the number of graphene layers led to a worsening of PCE (11.45% and 11.27% for the triple and four-fold layers, respectively). In fact, a high number of layers decreased the transmittance of the electrode, resulting in a lower number of photons that reached the perovskite phase.

The use of the inverted architecture also allows the elimination of expensive, brittle and rigid TCO substrates. In 2016, Sung *et al.* reported an inverted cell, using graphene as the transparent cathode.²¹⁷ MoO₃ was added to graphene to make its surface more hydrophilic, thus increasing the contact with the PEDOT:PSS used as the HTM, as shown in Fig. 14A–F. In addition, MoO₃ elevated the graphene work function from 4.23 to 4.71 eV, ameliorating the band alignment with the HTM. The best performing device showed a PCE of 16.1%, with a V_{oc} of 1.03 V, a J_{sc} of

21.9 mA cm⁻² and a FF of 0.72. The beneficial effect of MoO₃ was confirmed also by Yoon *et al.*,²¹⁸ who reported the same architecture of Sung,²¹⁷ but with superflexible polyethylene naphthalate (PEN) as the substrate. Devices with graphene/MoO₃ as the back electrode showed an average PCE of 15.0% ($V_{oc} = 0.99$ V, $J_{sc} = 21.0$ mA cm⁻², FF = 0.72), highlighting the role of MoO₃ in ensuring a better ohmic contact with the HTM.

A successful strategy for increasing the conductivity of carbon materials is nitrogen doping. In fact, the addition of lone pair electrons of nitrogen atoms can facilitate charge transfer. The nitrogen-doping of graphene for PSC application was performed by Zhu *et al.* in 2018.²¹⁹ Nitrogen-doped graphene framework (NGF) was used as the cathode material and ensured a good network for charge transfer. PV parameters confirmed the increased properties of the NGF with respect to undoped samples. In fact, the PCE shifted from 8.98% to 10.32%, for pristine and NGF-based devices, respectively.

Finally, in a noteworthy work, Lou *et al.* used only carbon-based materials as electrodes for the fabrication of PSCs, as shown in Fig. 14G.²²⁰ In particular, graphene was chosen as the anode and was deposited on a poly(ethylene terephthalate) (PET) flexible substrate, due to its high transparency and flexibility; cross-stacking CNTs were used as the back electrode material, due to their high electrical conductivity. The optimum number of graphene layers was two, as reported by You.¹⁶¹ This double layer device demonstrated a V_{oc} of 0.89 V, a J_{sc} of 20.25 mA cm⁻², a FF of 0.65 and a PCE of 11.9%, and photographs of its components are shown in Fig. 14H and I.

4 Carbon nanotube-based back electrodes

CNTs are hollow cylinders resulting from the rolling up of a graphene layer. From their discovery in 1991,²²¹ CNTs have attracted much attention in electronic and optoelectronic applications, due to their excellent charge transport ability, large hydrophobicity and high stability.²²² CNTs are p-type semiconductors, with work functions ranging from -4.95 to -5.05 eV, suitable for working as back electrodes in PSCs. Their application in the PSC field has already been reviewed.^{75,213} Li *et al.* reported the first example of the use of CNTs as a back electrode in PSCs.¹⁶⁰ They adopted an interfacial engineering method to improve the surface contact between CH₃NH₃PbI₃ and CNTs: drops of toluene were added on the top of CNT film after the deposition onto the perovskite phase. Toluene did not dissolve any phase, but wetted the surface of both films, driving CNTs toward CH₃NH₃PbI₃. PL quenching confirmed the strong adhesion through van der Waals interactions between the two films. As a result, this cell was able to convert solar radiation with a PCE of 6.87%.

Device performance can be dramatically increased by using MWCNTs,²²³ consisting of several CNTs stacked together providing a continuous and homogeneous film, strongly attached to the perovskite surface. This represents a strong advantage over other carbon-based materials, such as carbon black, which forms a loosely packed film easy to be cracked. Graphite forms

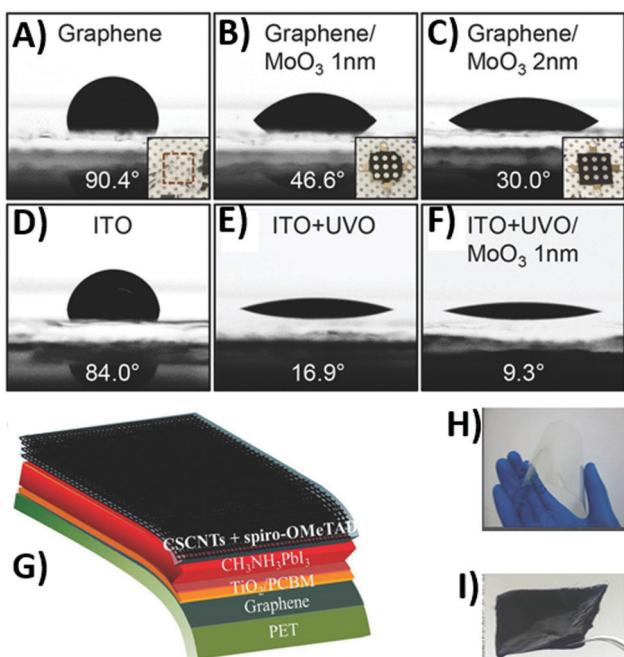


Fig. 14 Droplets of PEDOT:PSS on (A) as-prepared graphene, (B) graphene covered with 1 nm MoO₃, (C) graphene covered with 2 nm MoO₃, (D) as-prepared ITO, (E) ITO treated with UV/O₃, and (F) ITO covered with 1 nm MoO₃ after UV/O₃ treatment; the insets in (A–C) show the optical images of PEDOT:PSS/MAPbI₃ films fabricated on the corresponding glass/graphene surfaces. (G) Device architecture of an all-carbon-electrode-based flexible PSC; (H) photograph of as-fabricated cross-stacking CNTs/PET; (I) photograph of as-fabricated cross-stacking graphene/PET. Adapted and reprinted with permission from ref. 217 and 220.

a uniform layer too, but the larger particles do not lead to a perfect contact with the perovskite phase. In a HTM-free device, the use of MWCNTs as a back electrode provided a PCE of 10.30%.²²³

Zheng *et al.* made a further effort toward the optimization of MWCNTs for PSC application,²²⁴ starting from the idea that the work function of MWCTNs (−4.46 eV) was still too high compared with the VB of the perovskite. As already mentioned before,¹⁵⁷ the boron-doping of carbon-based materials is a suitable strategy to reduce their work function. Boron-doped MWCNTs were obtained by the reaction of MWCNTs with boric acid and subsequent thermal treatment, as shown in Fig. 15A. The product showed the same structure of MWCNTs, suggesting that boron can replace carbon without any change in the graphitic structure, and the thermal annealing reduced the number of defects. MWCNT- and boron-doped MWCNT-based devices attained average PCE values of 10.70% and 14.60%, respectively. The dramatic increase in PCE was ascribed to the ameliorated band alignment and improved charge extraction ability of boron-doped samples, as depicted in the scheme shown in Fig. 15B.

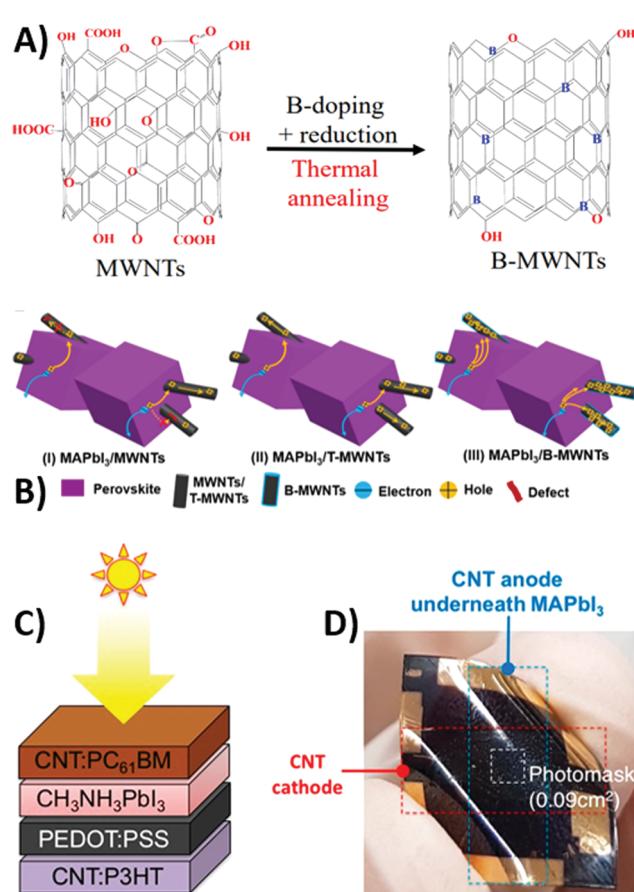


Fig. 15 (A) Schematic structure of MWCNTs before and after boron-doping and thermal treatment; (B) schematic diagram of the stronger hole extraction and transport capability of boron-MWCNTs (right) with respect to pristine MWCNTs (left) and thermally treated MWCNTs (center). (C) Schematic architecture of a CNTs/PC₆₁BM/CH₃NH₃PbI₃/PEDOT:PSS/CNTs device and (D) digital picture of a PET-based device, highlighting its remarkable flexibility. Adapted and reprinted with permission from ref. 224 and 226.

Like graphene,²²⁵ CNTs may also be exploited for the fabrication of transparent electrodes. In addition, their mechanical properties permit the use of flexible substrates, such as PET. In 2017 Jeon *et al.* demonstrated the use of CNTs as both front and back electrode materials.²²⁶ In these devices, the transparency of the electrode is fundamental to allow light reach the active material. In addition [6,6]-phenyl-C₆₁-butyric acid methyl ester (PC₆₁BM) and PEDOT:PSS were used as the ETM and HTM, respectively. This architecture (shown in Fig. 15C and D) was found to work well in both glass and PET-based flexible substrates, with a PCE of 7.3% and 7.1%, respectively.

As in the case of graphite and carbon black back electrodes, organic^{227–229} and inorganic¹⁴⁹ HTMs have been exploited to further increase the hole extraction ability of CNTs.^{230,231} Aitola *et al.* reported a CNT-based PSC with spiro-OMeTAD as the HTM.²²⁸ An average PCE of 14.3% was achieved, still lower than that obtained with gold as the back electrode (18.4%). However, CNTs strongly increased the stability of the device at relatively high temperatures (60 °C): while the gold-based device degraded dramatically, exhibiting a loss of 20% in just 8 h, the CNT-based device was highly stable (loss of 0.04% in the same time). The migration of gold atoms and the penetration of air moisture were responsible for the degradation of the perovskite layer. On the other hand, these phenomena were suppressed by the use of hydrophobic CNTs.

P3HT is another suitable hydrophobic HTM for PSCs. It has already been used for graphite, carbon black and graphene electrodes.^{188,189} When used with CNTs, it acts as a strong crosslinker that binds together CNTs.²²⁷ Therefore, a uniform morphology and a network for charge transfer are obtained by using P3HT as an organic/polymeric HTM. With an optimized concentration of 2 mg mL^{−1} in the precursor solution, an average PCE of 12.54% was obtained ($V_{oc} = 0.90$ V, $J_{sc} = 22.21$ mA cm^{−2}, FF = 0.63).²²⁷ Below this concentration, the amount of P3HT was not enough to connect CNTs. On the other hand, above this concentration the excess of P3HT blocked the conductive pathway, increasing recombination phenomena.

A similar strategy involves the use of poly(ethylenimine) (PEI) in the CNT film.²²⁹ PEI played the important role of ameliorating the interface between carbon and PC₆₁BM, the latter being used as an electron acceptor in inverted FTO/NiO/CH₃NH₃PbI₃/PC₆₁BM/CNTs:PEI architectures. The beneficial effect of PEI was demonstrated by the dramatic increase in PCE, *i.e.* 10.8% *vs.* 3.3% for the PEI-free device. This result was ascribed to the better contact and decreased energy barrier between CNTs and PC₆₁BM.

Last, a p-type NiO semiconductor was demonstrated to work as a HTM in carbon-based PSCs.^{150–152,194} In 2017, Liu *et al.* reported the use of NiO as the HTM in fully printable CNT-based devices.¹⁴⁹ The energy level of the NiO/CNTs composite matched well with that of the perovskite, ensuring a good hole extraction rate. The addition of NiO to the carbon material allowed the reduction of the thickness of the electrode (1.8 μm), while keeping the electrical conductivity constant. As a matter of fact, this device attained an average PCE of 12.7% ($V_{oc} = 0.945$ V, $J_{sc} = 20.7$ mA cm^{−2}, FF = 0.64), while the corresponding device with 1.8 μm-thick graphite achieved a PCE of only 6.2%.

5 Stability of carbon-based PSCs

This review has clearly highlighted that using noble metals is problematic and expensive, but the main drawback for the commercialization of PSCs is the poor long-term stability of the devices. Being carbon electrode-based devices the best performing architectures in terms of stability, this advantage will be further stressed in this section. Stability is a widely discussed topic in the PSC framework, and the authors of this review agree with the general opinion that tests carried out under maximum power point (MPP) conditions possess wider significance than the vast majority of shelf stability tests reported in the literature.²³² Therefore, even though it was surprisingly noted that the vast majority of research groups proposed shelf stability tests for their carbon-based devices,^{233–234} this section highlights the most significant results achieved under MPP conditions.

Bashir *et al.* investigated the stability of a HTM-free device fabricated with a thin layer of copper-doped nickel oxide (Cu:NiO_x) NPs, which helped in improving the photocurrent and reducing the recombination resistance.³²⁵ MPP tracking was performed and the output current density was monitored under continuous illumination with a constant applied bias of 0.62 V. The current remained above 20 mA cm^{-2} for more than 50 h, and the device showed no sign of degradation for 60 h (see Fig. 16A). Moreover, a slight increase in current was observed during the experiment, and this was attributed to the interaction of the perovskite layer with ambient humidity. These researchers also fabricated a monolithic perovskite module on a 100 cm^2 glass substrate (active area = 70 cm^2) and the champion device showed an impressive PCE of 12.1%.

Almost all of the carbon-based PSCs reported so far have been fabricated using TiO_2 as the ETM, the latter requiring a high-temperature sintering process. As an alternative, Zhou *et al.* proposed solution-processed hexamethonium bromide (HMB)-doped C_{60} as the ETM, achieving a high PCE of over 16% without hysteresis.³²⁶ The remarkable stability of the resulting PSCs allows them to maintain nearly 90% of the initial performance after continuous operation for 338 h at MPP under 1 sun illumination in ambient air and with a 420 nm cut-off UV filter (see Fig. 16B).

Coupling carbon-based electrodes with all-air processing would truly lead to an easily upscalable PSC fabrication procedure. This goal was achieved by Zhou *et al.*, who prepared MWCNT-incorporated $\text{FA}_x\text{MA}_{1-x}\text{PbI}_y\text{Br}_{3-y}$ perovskite films in ambient air, where hydrophobic MWCNTs mediated the crystallization of the perovskite and prevented the erosion by moisture.³²⁷ With the low annealing temperature ($<150^\circ\text{C}$) adopted, a PCE of 16.25% was achieved and the photostability of the devices without encapsulation was studied by MPP tracking under continuous 1 sun illumination at a RH of 30–80%. Cells fabricated with 0.5% MWCNTs maintained 94.9% of the initial PCE after 500 h, while pristine devices retained only 23.4% after 200 h, as shown in Fig. 16C.

The self-adhesive macroporous carbon electrodes proposed by Zhang *et al.* and previously described in this review were

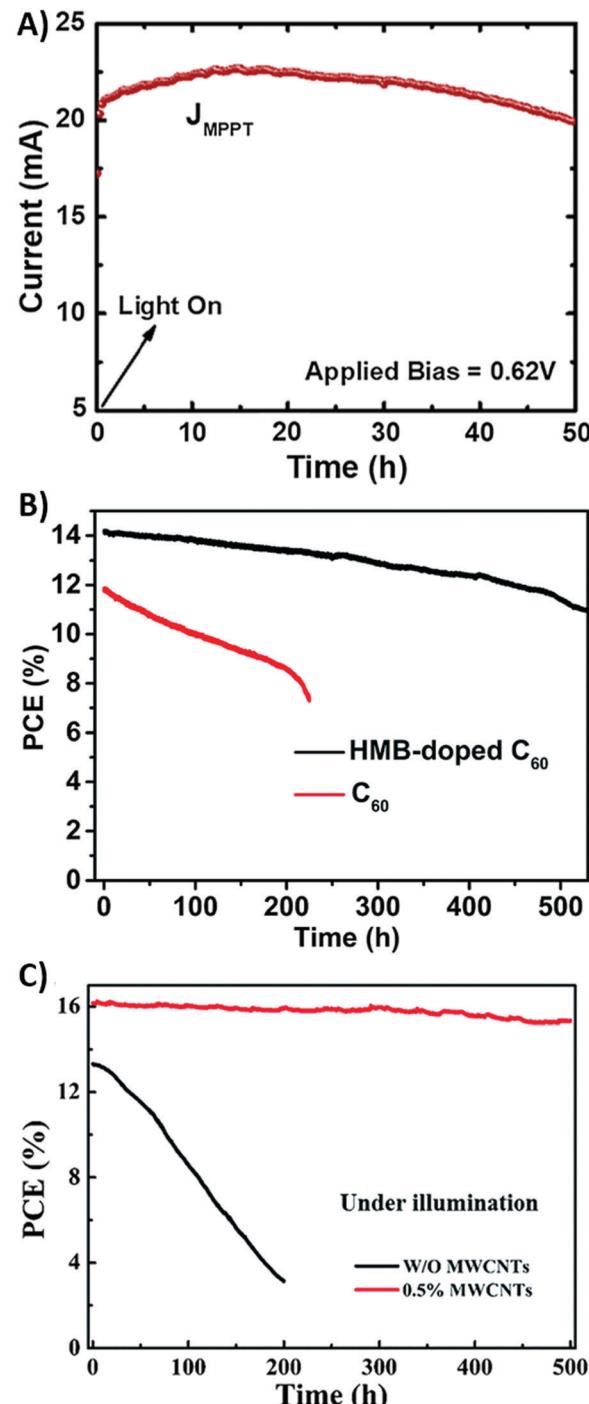


Fig. 16 Aging tests at MPP under light for: (A) a PSC containing carbon and Cu:NiO_x HTM; (B) C_{60} - and HMB-doped C_{60} PSCs (with a 420 nm cut-off UV filter, under ambient conditions); (C) carbon-based PSCs with different MWCNT doping contents (in air with a RH of 30–80%). Adapted and reprinted with permission from ref. 325–327.

subjected to an aging test under a N_2 atmosphere, full AM1.5 sun-equivalent and UV-free conditions at the MPP.¹⁷⁸ Gold-based PSCs suffered from much faster degradation due to the chemical reaction between the perovskite and gold, retaining just 22% of the initial PCE after 80 h (see Fig. 17A). Conversely, carbon-based



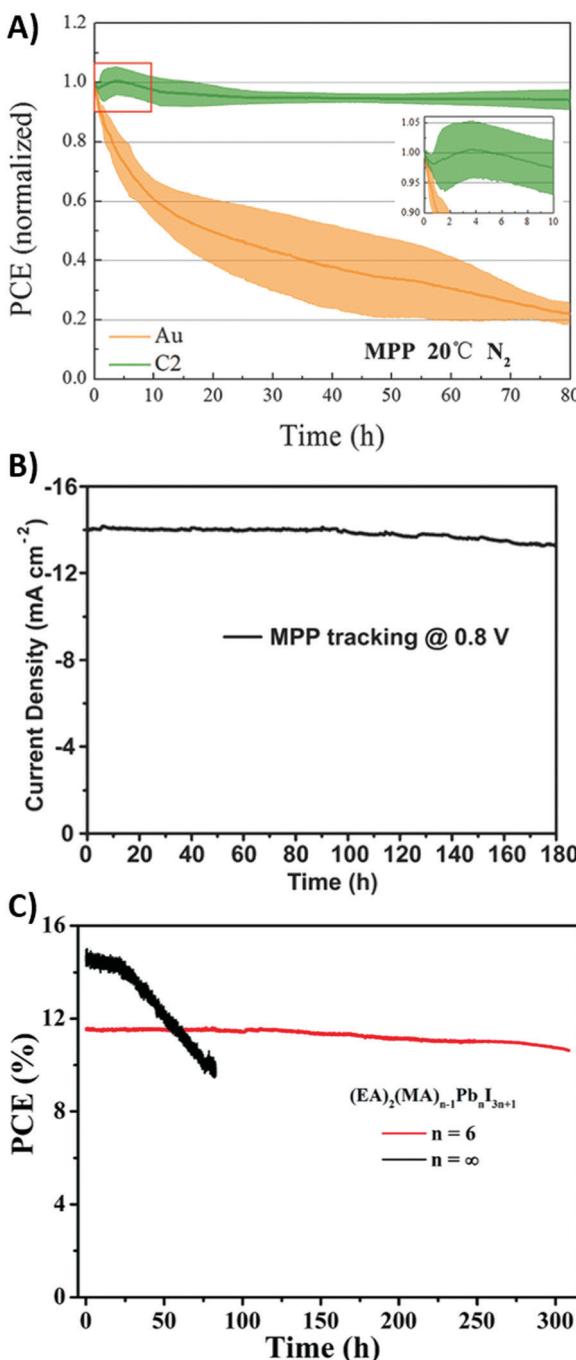


Fig. 17 Aging tests at the MPP under light for: (A) gold- and carbon-based PSCs (the shaded area represents the standard deviation, and the inset shows the detailed degradation characteristics of carbon-based cells during the first 10 h); (B) C₆₀-based PSC (with a 420 nm cut-off UV filter and RH of 40–60%); (C) (EA)₂(MA)_{n-1}Pb_nI_{3n+1} devices ($n = 6, \infty$) (RH of 30–80%). Adapted and reprinted with permission from ref. 60, 178 and 328.

devices exhibited a short rapid degradation and subsequent recovery, due to the improvement of the back contact between the electrode and spiro-OMeTAD; this phenomenon was attributed to an interface passivation caused by ion migration under illumination and an electric field. Carbon-based cells retained

over 94% of the initial PCE, indicating greatly improved stability with respect to their gold-based counterparts.

Meng *et al.* fabricated a carbon-based PSC without a HTM and using C₆₀ as the ETM, reaching a PCE of 15.38% without hysteresis.³²⁸ Besides improved electron extraction, suppressed charge recombination and reduced sub-bandgap states at the C₆₀/MAPbI₃ interface, the device showed moisture and ion migration resistance. As shown in Fig. 17B, the long-term stability was tested under continuous 1 sun illumination (with a 420 nm UV filter) at the MPP, and the devices assembled without any encapsulation retained 95% of their initial performance after 180 h in air, with a RH of 40–60%.

Since the commonly used MAPbI₃ photoabsorber is ambient-unstable and incompatible with the low-cost mass-production of carbon-based PSCs, Zhou *et al.* fabricated (EA)₂(MA)_{n-1}Pb_nI_{3n+1} films ($n = 20, 10, 6$) and assembled ITO/C₆₀/(EA)₂(MA)_{n-1}Pb_nI_{3n+1}/C devices with PCE exceeding 11.88%.⁶⁰ The photostability was assessed without encapsulation, by MPP tracking under continuous 1 sun illumination (without a cut-off UV filter) in air with a RH of 30–80%. The PCE was retained at 91.8% after 308 h, while that of the reference cell fabricated with MAPbI₃ dropped to 66.5% of the initial value after 83 h, as shown in Fig. 17C.

The inorganic interlayer of spinel Co₃O₄ used by Bashir *et al.* to suppress charge recombination and extract holes efficiently, and described in the previous sections of this review, was further investigated in aging tests at the MPP.¹⁵⁸ A slight increase in J_{sc} was observed (see Fig. 18A), attributed to the interaction of the perovskite layer with ambient humidity, and the perovskite modules showed a degradation lower than 10% after continuous light soaking for 140 h.

Excess PbI₂ is commonly considered as a way to boost the PCE in standard PSCs, and Kapoor *et al.* checked this issue in fully printable carbon-based devices.³²⁹ An improvement in V_{oc} was detected, while other parameters remained unchanged. Continuous simulated solar illumination under ambient conditions (25 °C and 65% RH) and the MPP was carried out for 68 h. Fig. 18B shows that no decrease of current was detected for the standard device, whereas the current reduced by 10% for the device containing 15% excess PbI₂.

A 140 h MPP tracking of gold- and single-walled CNT-contacted devices under illumination at 1 sun in a N₂ atmosphere was carried out by Aitola *et al.*²²⁸ The cells were kept at 20 °C for the first 14 h, and the gold-based cell showed pronounced changes; then, a stabilization period occurred, which was not seen in high temperature experiments, where gold-based devices underwent an irreversible degradation process. Noteworthily, the CNT-based device exhibited only a small PCE drop in this region, as shown in Fig. 18C.

Carbon cloth and carbon fibers, widely used in DSSCs and batteries, replaced gold in a batch of PSCs proposed by Gholipour *et al.*³³⁰ The optimized device configuration led to a PCE of 14.8%. Long-term stability was studied under a N₂ atmosphere, 85 °C, constant 1 sun illumination and MPP tracking. While the gold-based cell suffered from rapid degradation, retaining less than 20% of the initial PCE after 20 h and less than 10% after 65 h, the carbon-based cell retained close to half of the starting

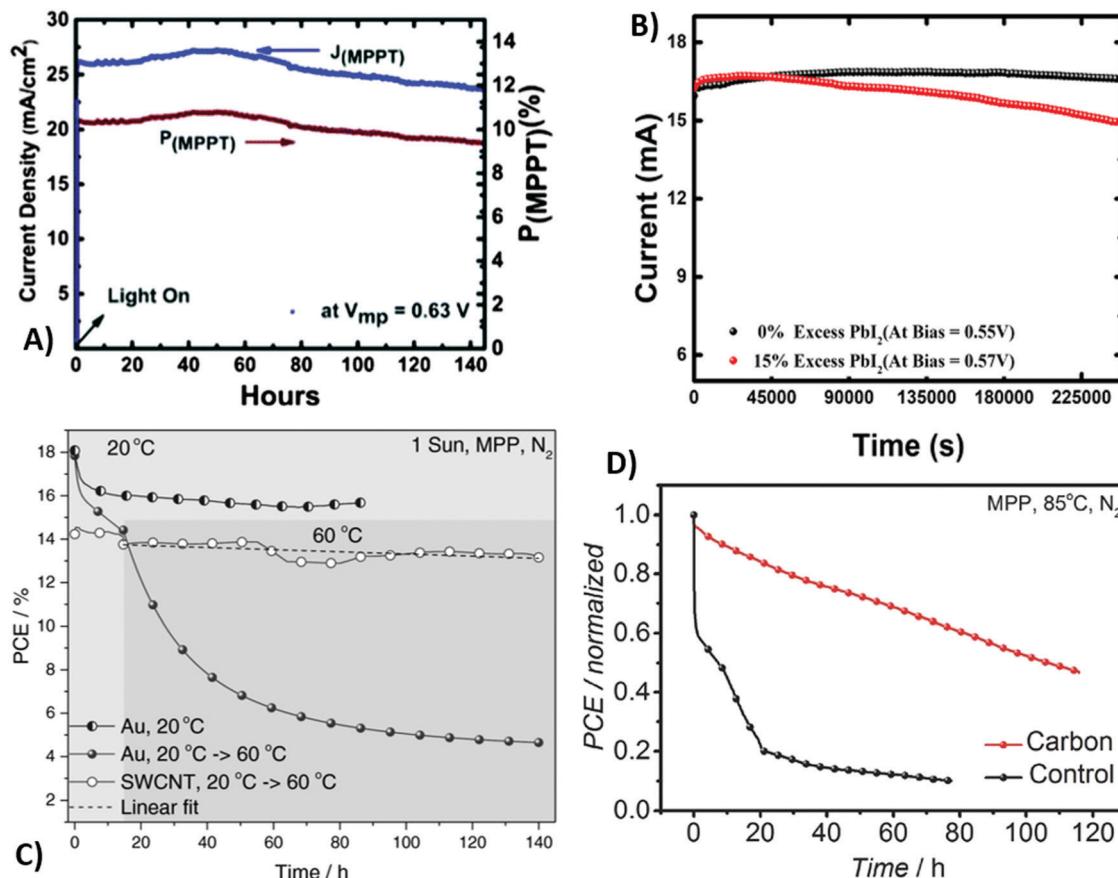


Fig. 18 Aging tests at the MPP under light for: (A) a Co_3O_4 /carbon solar cell; (B) carbon-based PSC with or without PbI_2 excess; (C) gold- and single-walled CNT-contacted devices at elevated temperatures; (D) carbon cloth- and gold-based cells (under a N_2 atmosphere, 85 °C). Adapted and reprinted with permission from ref. 158, 228, 329 and 330.

PCE after 115 h (see Fig. 18D). This slight degradation of the carbon-based cell was attributed to chemical reactions between spiro-OMeTAD⁺ and migrating I^- , hampering the conductivity of the HTM and thus the solar cell performance.

Several articles among those mentioned in this section focused on aging tests based on external degradation agents (e.g., moisture, oxygen, etc.), but no insight into the intrinsic degradation vector from the perovskite itself (releasing reactive gases) or studies of the true chemical inertness properties of carbon layers were provided, along with comparison with reference molecular/polymer-based HTMs. For sure it can be stated that, in the absence of HTMs, 4-*tert*-butylpyridine and organic lithium salt additives (typically used to dope spiro-OMeTAD) will not diffuse into the perovskite layer or absorb water traces; this surely improves the intrinsic stability of carbon-based devices. As a further advantage, carbon is not prone to formation of metal halides as many metal electrodes used in the PSC field do, leading to high resistivity and iodide deficiency in the perovskite layer. Moreover, carbon has not been demonstrated to penetrate the semiconductor material, while it is well known in the PSC community that Au diffuses through the perovskite. To further strengthen the solidity of carbon-based back electrodes in HTM-free devices, *in situ* analytical studies upon aging, highlighting the intrinsic stability of cell components, are required.

6 Conclusions

This review has summarized the most significant outcomes on PSC fabrication, characterization and scale up when carbon-based back electrodes are used. These platforms, prepared with graphite, carbon black, graphene or CNTs, exhibited significantly high stability, especially due to the high water resistance property of carbon. Research groups have proposed several processing routes, from scalable screen-printing approaches to inkjet printing, slot-die coating, and electrodeposition. The main trend in the literature scenario highlights that the PCE values of carbon electrode-based PSCs are lower than those of their gold-based counterparts, and the main reason lies in the poor contact at the perovskite/electrode interface; as secondary issues, resistance of carbon electrodes and charge recombination phenomena also contribute to lower J_{sc} and FF values.

As a solution, current trends highlighted in this review show that interfacial engineering of carbon-based PSCs is becoming a fruitful research field, where scientists are working to decrease the heterogeneity in (opto)electronic properties of perovskites and carbon films and passivating their defects, thus boosting charge transfer and reducing recombination.

A further challenge in the long (but in rapid evolution) path towards gold-free PSCs will be the investigation behind the

markedly improved stability of carbon-based devices. Indeed, even though many groups have carried out long-term stability experiments, not much is understood on the relationship between the singular aging of internal interfaces and components, and to what extent they affect the overall device stability against different external stress sources.

Conflicts of interest

There are no conflicts to declare.

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